

## 6-Bit, Programmable 2-/3-/4-Phase, Synchronous Buck Controller

# ADP3190

## FEATURES

### Selectable 2-, 3-, or 4-phase operation at up to

**1 MHz per phase**

**±9.5 mV worst-case differential sensing error**

**over temperature**

### Logic-level PWM outputs for interface to external

## high power drivers

**PWM Flex-Mode™ architecture for excellent load**

## transient performance

### Active current balancing between all output phases

### Built-in power-good/crowbar blanking supports on-the-fly

### VID code changes

**6-bit, digitally programmable 0.8375 V to 1.6 V output**

### Programmable short circuit protection with programmable latch-off delay

## APPLICATIONS

## Desktop PC power supplies for

**Next generation Intel® processors**

## VRM modules

## Game consoles

## GENERAL DESCRIPTION

The ADP3190<sup>1</sup> is a highly efficient, multiphase, synchronous buck switching regulator controller optimized for converting a 5 V (ADP3190A) or 12 V (ADP3190) main supply into the core supply voltage required by high performance Intel processors. The part uses an internal 6-bit DAC to read a voltage identification (VID) code directly from the processor, which is used to set the output voltage between 0.8375 V and 1.6 V. The devices use a multimode PWM architecture to drive the logic-level outputs at a programmable switching frequency that can be optimized for VR size and efficiency. The phase relationship of the output signals can be programmed to provide 2-, 3-, or 4-phase operation, allowing for the construction of up to four complementary buck switching stages.

The ADP3190 includes programmable, no-load offset and slope functions to adjust the output voltage as a function of the load current, so it is always optimally positioned for a system transient. The ADP3190 also provides accurate and reliable short-circuit protection, adjustable current limiting, and a delayed power-good output that accommodates on-the-fly output voltage changes requested by the CPU.

## FUNCTIONAL BLOCK DIAGRAM

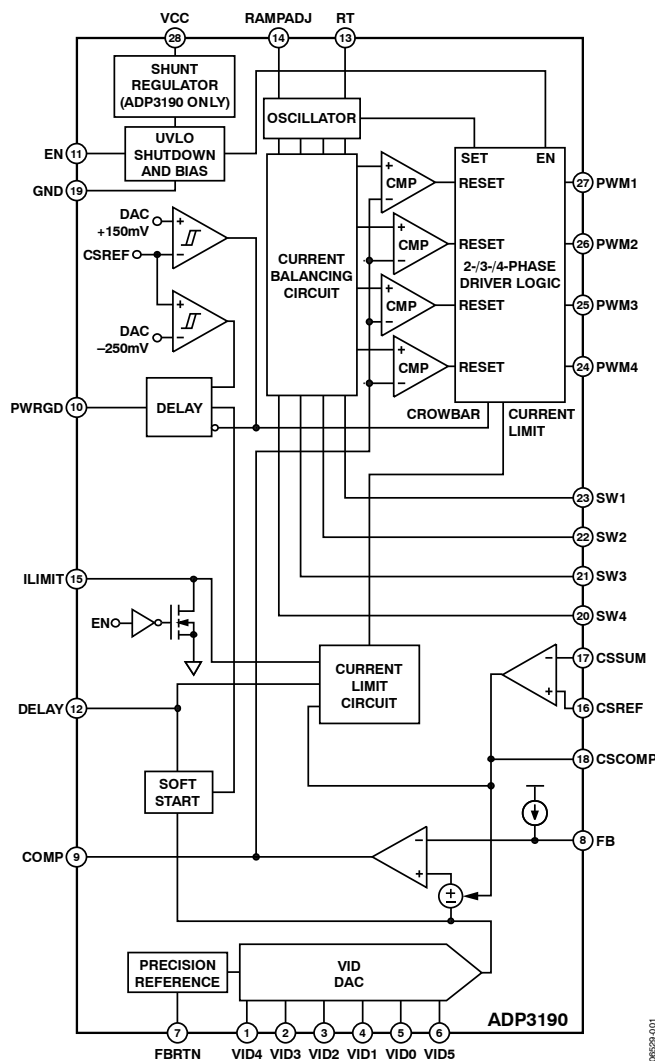


Figure 1.

The ADP3190 is a replacement for the ADP3188. A built-in shunt regulator allows the part to be connected to the 12 V system supply through a series resistor.

The device is specified over the commercial temperature range of 0°C to 85°C and is available in a 28-lead TSSOP and a 28-lead QSOP.

<sup>1</sup> Protected by U. S. Patent Number 6,683,441; other patents pending.

## TABLE OF CONTENTS

|                                                              |    |                                                                   |    |
|--------------------------------------------------------------|----|-------------------------------------------------------------------|----|
| Features .....                                               | 1  | Application Information .....                                     | 14 |
| Applications .....                                           | 1  | Setting the Clock Frequency .....                                 | 14 |
| General Description .....                                    | 1  | Soft Start and Current-Limit Latch-Off Delay Times .....          | 14 |
| Functional Block Diagram .....                               | 1  | Inductor Selection .....                                          | 14 |
| Revision History .....                                       | 2  | Designing an Inductor .....                                       | 15 |
| Specifications .....                                         | 3  | Output Droop Resistance .....                                     | 15 |
| Absolute Maximum Ratings .....                               | 5  | Inductor DCR Temperature Correction .....                         | 16 |
| ESD Caution .....                                            | 5  | Output Offset .....                                               | 16 |
| Pin Configuration and Function Descriptions .....            | 6  | C <sub>OUT</sub> Selection .....                                  | 17 |
| Typical Performance Characteristics and Test Circuits .....  | 7  | Power MOSFETs .....                                               | 17 |
| Theory of Operation .....                                    | 8  | Ramp Resistor Selection .....                                     | 19 |
| Startup Sequence .....                                       | 8  | COMP Pin Ramp .....                                               | 19 |
| Master Clock Frequency .....                                 | 8  | Current-Limit Setpoint .....                                      | 19 |
| Output Voltage Differential Sensing .....                    | 8  | Feedback Loop Compensation Design .....                           | 19 |
| Output Current Sensing .....                                 | 8  | C <sub>IN</sub> Selection and Input Current dI/dt Reduction ..... | 21 |
| Active Impedance Control Mode .....                          | 9  | Tuning the ADP3190 .....                                          | 21 |
| Current-Control Mode and Thermal Balance .....               | 9  | Replacing the ADP3188 with the ADP3190 .....                      | 23 |
| Voltage Control Mode .....                                   | 9  | Choosing Between the ADP3190 and the ADP3190A .....               | 24 |
| Soft Start .....                                             | 9  | Layout and Component Placement .....                              | 25 |
| Current-Limit, Short-Circuit, and Latch-Off Protection ..... | 10 | General Recommendations .....                                     | 25 |
| Dynamic VID .....                                            | 10 | Power Circuitry Recommendations .....                             | 25 |
| Power-Good Monitoring .....                                  | 12 | Signal Circuitry Recommendations .....                            | 25 |
| Output Crowbar .....                                         | 12 | Outline Dimensions .....                                          | 26 |
| Output Enable and UVLO .....                                 | 12 | Ordering Guide .....                                              | 26 |

## REVISION HISTORY

### 01/08 - Rev 2: Conversion to ON Semiconductor

#### 2/07—Rev. 0 to Rev. A

|                            |    |
|----------------------------|----|
| Changes to Figure 5 .....  | 7  |
| Changes to Figure 9 .....  | 13 |
| Changes to Figure 17 ..... | 24 |
| Changes to Figure 18 ..... | 25 |

#### 1/06—Revision 0: Initial Version

## SPECIFICATIONS

VCC = 5 V, FBRTN = GND, T<sub>A</sub> = 0°C to 85°C, unless otherwise noted.<sup>1</sup>

Table 1.

| Parameter                                         | Symbol                   | Conditions                                                                                                                                                                                                           | Min  | Typ  | Max  | Unit |
|---------------------------------------------------|--------------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------|------|------|------|
| <b>ERROR AMPLIFIER</b>                            |                          |                                                                                                                                                                                                                      |      |      |      |      |
| Output Voltage Range                              | V <sub>COMP</sub>        | Relative to nominal DAC output, referenced to FBRTN, CSSUM = CSCOMP, V <sub>OUT</sub> < 1 V<br>Relative to nominal DAC output, referenced to FBRTN, CSSUM = CSCOMP, V <sub>OUT</sub> > 1 V<br>VCC = 4.75 V to 5.25 V | 0    |      | VCC  | V    |
| Accuracy                                          | V <sub>FB</sub>          |                                                                                                                                                                                                                      | −8.0 |      | +8.0 | mV   |
|                                                   |                          |                                                                                                                                                                                                                      | −9.5 |      | +9.5 | mV   |
| Line Regulation                                   | ΔV <sub>FB</sub>         |                                                                                                                                                                                                                      |      | 0.05 |      | %    |
| Input Bias Current                                | I <sub>FB</sub>          |                                                                                                                                                                                                                      | 14   | 15.5 | 17   | μA   |
| FBRTN Current                                     | I <sub>FBRTN</sub>       |                                                                                                                                                                                                                      |      | 100  | 140  | μA   |
| Output Current                                    | I <sub>O(ERR)</sub>      | FB forced to V <sub>OUT</sub> − 3%                                                                                                                                                                                   |      | 500  |      | μA   |
| Gain Bandwidth Product                            | GBW <sub>(ERR)</sub>     | COMP = FB                                                                                                                                                                                                            |      | 20   |      | MHz  |
| Slew Rate                                         |                          | C <sub>COMP</sub> = 10 pF                                                                                                                                                                                            |      | 25   |      | V/μs |
| <b>VID INPUTS</b>                                 |                          |                                                                                                                                                                                                                      |      |      |      |      |
| Input Low Voltage                                 | V <sub>IL(VID)</sub>     | VID(X) = 0 V                                                                                                                                                                                                         |      |      | 0.4  | V    |
| Input High Voltage                                | V <sub>IH(VID)</sub>     |                                                                                                                                                                                                                      | 0.8  |      |      | V    |
| Input Current, Input Voltage Low                  | I <sub>IL(VID)</sub>     | VID(X) = 1.25 V                                                                                                                                                                                                      |      | −25  | −35  | μA   |
| Input Current, Input Voltage High                 | I <sub>IH(VID)</sub>     |                                                                                                                                                                                                                      |      | 5    | 15   | μA   |
| Pull-Up Resistance                                | R <sub>VID</sub>         |                                                                                                                                                                                                                      | 35   | 60   | 85   | kΩ   |
| Internal Pull-Up Voltage                          |                          |                                                                                                                                                                                                                      | 1.0  | 1.2  |      | V    |
| VID Transition Delay Time <sup>2</sup>            |                          | VID code change to FB change                                                                                                                                                                                         | 400  |      |      | ns   |
| No CPU Detection Turn-off Delay Time <sup>2</sup> |                          | VID code change to 11111 to PWM going low                                                                                                                                                                            | 400  |      |      | ns   |
| <b>OSCILLATOR</b>                                 |                          |                                                                                                                                                                                                                      |      |      |      |      |
| Frequency Range <sup>2</sup>                      | f <sub>OSC</sub>         | T <sub>A</sub> = 25°C, R <sub>T</sub> = 225 kΩ, 4-phase<br>T <sub>A</sub> = 25°C, R <sub>T</sub> = 100 kΩ, 4-phase<br>T <sub>A</sub> = 25°C, R <sub>T</sub> = 30 kΩ, 4-phase<br>R <sub>T</sub> = 100 kΩ to GND       | 0.25 |      | 4    | MHz  |
| Frequency Variation                               | f <sub>PHASE</sub>       |                                                                                                                                                                                                                      | 155  | 200  | 245  | kHz  |
|                                                   |                          |                                                                                                                                                                                                                      |      | 400  |      | kHz  |
|                                                   |                          |                                                                                                                                                                                                                      |      | 600  |      | kHz  |
| Output Voltage                                    | V <sub>RT</sub>          |                                                                                                                                                                                                                      | 1.8  | 2.0  | 2.3  | V    |
| RAMPADJ Output Voltage                            | V <sub>RAMPADJ</sub>     | RAMPADJ – FB                                                                                                                                                                                                         | −50  |      | +50  | mV   |
| RAMPADJ Input Current Range                       | I <sub>RAMPADJ</sub>     |                                                                                                                                                                                                                      | 0    |      | 100  | μA   |
| <b>CURRENT SENSE AMPLIFIER</b>                    |                          |                                                                                                                                                                                                                      |      |      |      |      |
| Offset Voltage                                    | V <sub>OS(CSA)</sub>     | CSSUM – CSREF                                                                                                                                                                                                        | −1.5 |      | +1.5 | mV   |
| Input Bias Current                                | I <sub>BIAS(CSSUM)</sub> |                                                                                                                                                                                                                      | −10  |      | +10  | nA   |
| Gain Bandwidth Product                            | GBW <sub>(CSA)</sub>     |                                                                                                                                                                                                                      |      | 10   |      | MHz  |
| Slew Rate                                         |                          | C <sub>CSCOMP</sub> = 10 pF                                                                                                                                                                                          |      | 10   |      | V/μs |
| Input Common-Mode Range                           |                          | CSSUM and CSREF                                                                                                                                                                                                      | 0    |      | 3    | V    |
| Positioning Accuracy                              | ΔV <sub>FB</sub>         | See Figure 5                                                                                                                                                                                                         | −77  | −80  | −83  | mV   |
| Output Voltage Range                              |                          |                                                                                                                                                                                                                      | 0.05 |      | VCC  | V    |
| Output Current                                    | I <sub>CSCOMP</sub>      |                                                                                                                                                                                                                      |      | 500  |      | μA   |
| <b>CURRENT BALANCE CIRCUIT</b>                    |                          |                                                                                                                                                                                                                      |      |      |      |      |
| Common-Mode Range                                 | V <sub>SWxCM</sub>       |                                                                                                                                                                                                                      | −600 |      | +200 | mV   |
| Input Resistance                                  | R <sub>SWx</sub>         | SWx = 0 V                                                                                                                                                                                                            | 12   | 20   | 28   | kΩ   |
| Input Current                                     | I <sub>SWx</sub>         | SWx = 0 V                                                                                                                                                                                                            | 5    | 11   | 17   | μA   |
| Input Current Matching <sup>3</sup>               | ΔI <sub>SWx</sub>        | SWx = 0 V                                                                                                                                                                                                            | −5   |      | +5   | %    |

# ADP3190

| Parameter                           | Symbol           | Conditions                                                                                    | Min  | Typ  | Max  | Unit              |
|-------------------------------------|------------------|-----------------------------------------------------------------------------------------------|------|------|------|-------------------|
| <b>CURRENT-LIMIT COMPARATOR</b>     |                  |                                                                                               |      |      |      |                   |
| Output Voltage                      |                  |                                                                                               |      |      |      |                   |
| Normal Mode                         | $V_{ILIMIT(NM)}$ | $EN > 0.8\text{ V}$ , $R_{LIMIT} = 250\text{ k}\Omega$                                        | 2.8  | 3    | 3.3  | V                 |
| In Shutdown                         | $V_{ILIMIT(SD)}$ | $EN < 0.4\text{ V}$ , $I_{LIMIT} = -100\text{ }\mu\text{A}$                                   |      |      | 400  | mV                |
| Output Current, Normal Mode         | $I_{LIMIT(NM)}$  | $EN > 0.8\text{ V}$ , $R_{LIMIT} = 250\text{ k}\Omega$                                        |      | 12   |      | $\mu\text{A}$     |
| Maximum Output Current <sup>2</sup> |                  |                                                                                               | 60   |      |      | $\mu\text{A}$     |
| Current-Limit Threshold Voltage     | $V_{CL}$         | $V_{CSREF} - V_{CSCOMP}$ , $R_{LIMIT} = 250\text{ k}\Omega$                                   | 105  | 125  | 145  | mV                |
| Current-Limit Setting Ratio         |                  | $V_{CL}/I_{LIMIT}$                                                                            |      | 10.4 |      | mV/ $\mu\text{A}$ |
| DELAY Normal Mode Voltage           | $V_{DELAY(NM)}$  | $R_{DELAY} = 250\text{ k}\Omega$                                                              | 2.8  | 3    | 3.3  | V                 |
| DELAY Overcurrent Threshold         | $V_{DELAY(OC)}$  | $R_{DELAY} = 250\text{ k}\Omega$                                                              | 1.6  | 1.9  | 2.2  | V                 |
| Latch-Off Delay Time                | $t_{DELAY}$      | $R_{DELAY} = 250\text{ k}\Omega$ , $C_{DELAY} = 12\text{ nF}$                                 |      | 1.5  |      | ms                |
| <b>SOFT START</b>                   |                  |                                                                                               |      |      |      |                   |
| Output Current, Soft Start Mode     | $I_{DELAY(SS)}$  | During startup, $DELAY < 2.8\text{ V}$ ,                                                      | 15   | 20   | 25   | $\mu\text{A}$     |
| Soft Start Delay Time               | $t_{DELAY(SS)}$  | $R_{DELAY} = 250\text{ k}\Omega$ , $C_{DELAY} = 12\text{ nF}$ ,<br>$VID\text{ code} = 011111$ |      | 1    |      | ms                |
| <b>ENABLE INPUT</b>                 |                  |                                                                                               |      |      |      |                   |
| Input Low Voltage                   | $V_{IL(EN)}$     |                                                                                               |      |      | 0.4  | V                 |
| Input High Voltage                  | $V_{IH(EN)}$     |                                                                                               | 0.8  |      |      | V                 |
| Input Current                       | $I_{IL(EN)}$     |                                                                                               | -1   |      | +1   | $\mu\text{A}$     |
| <b>POWER-GOOD COMPARATOR</b>        |                  |                                                                                               |      |      |      |                   |
| Undervoltage Threshold              | $V_{PWRGD(UV)}$  | Relative to nominal DAC output                                                                | -180 | -250 | -300 | mV                |
| Overvoltage Threshold               | $V_{PWRGD(OV)}$  | Relative to nominal DAC output                                                                | 90   | 150  | 200  | mV                |
| Output Low Voltage                  | $V_{OL(PWRGD)}$  | $I_{PWRGD(SINK)} = 4\text{ mA}$                                                               |      | 225  | 400  | mV                |
| Power-Good Delay Time               |                  | $R_{DELAY} = 250\text{ k}\Omega$ , $C_{DELAY} = 12\text{ nF}$ ,<br>$VID\text{ code} = 011111$ | 1    |      |      | ms                |
| During Soft Start                   |                  |                                                                                               |      |      |      |                   |
| VID Code Changing                   |                  |                                                                                               | 100  | 250  |      | $\mu\text{s}$     |
| VID Code Static                     |                  |                                                                                               |      | 200  |      | ns                |
| Crowbar Trip Point                  | $V_{CROWBAR}$    | Relative to nominal DAC output                                                                | 90   | 150  | 200  | mV                |
| Crowbar Reset Point                 |                  | Relative to FBRTN                                                                             | 450  | 550  | 650  | mV                |
| Crowbar Delay Time                  | $t_{CROWBAR}$    | Overvoltage to PWM going low                                                                  |      |      |      |                   |
| VID Code Changing                   |                  | Blanking time                                                                                 | 100  | 250  |      | $\mu\text{s}$     |
| VID Code Static                     |                  |                                                                                               |      | 400  |      | ns                |
| <b>PWM OUTPUTS</b>                  |                  |                                                                                               |      |      |      |                   |
| Output Low Voltage                  | $V_{OL(PWM)}$    | $I_{PWM(SINK)} = -400\text{ }\mu\text{A}$                                                     |      | 160  | 500  | mV                |
| Output High Voltage                 | $V_{OH(PWM)}$    | $I_{PWM(SOURCE)} = +400\text{ }\mu\text{A}$                                                   | 4.0  | 5    |      | V                 |
| <b>SUPPLY—ADP3190<sup>4</sup></b>   |                  |                                                                                               |      |      |      |                   |
| VCC                                 | VCC              | $V_{SYSTEM} = 12\text{ V}$ , $R_{SHUNT} = 240\text{ }\Omega$ , see Figure 4                   |      | 5    |      | V                 |
| DC Supply Current                   |                  |                                                                                               |      | 20   | 30   | mA                |
| UVLO Threshold Voltage              | $V_{UVLO}$       | VCC rising                                                                                    | 6.3  | 7    | 8.0  | V                 |
| UVLO Hysteresis                     |                  |                                                                                               |      | 0.9  |      | V                 |
| <b>SUPPLY—ADP3190A<sup>4</sup></b>  |                  |                                                                                               |      |      |      |                   |
| VCC                                 | VCC              | $V_{SYSTEM} = 5\text{ V}$ , $R_{SHUNT} = 10\text{ }\Omega$ , see Figure 4                     |      | 5    |      | V                 |
| DC Supply Current                   |                  |                                                                                               |      | 7    | 12   | mA                |
| UVLO Threshold Voltage              | $V_{UVLO}$       | VCC rising                                                                                    | 3.7  | 4.0  | 4.3  | V                 |
| UVLO Hysteresis                     |                  |                                                                                               |      | 0.9  |      | V                 |

<sup>1</sup> All limits at temperature extremes are guaranteed via correlation using standard statistical quality control (SQC).

<sup>2</sup> Guaranteed by design, not production tested. Specifications subject to change without notice.

<sup>3</sup> Relative current matching from each phase to the average of all four phases.

<sup>4</sup> System supply is the only difference between the ADP3190 and ADP3190A. All other parameters are the same for the two models.

# ABSOLUTE MAXIMUM RATINGS

Table 2.

| Parameter                           | Rating                |
|-------------------------------------|-----------------------|
| VCC                                 | −0.3 V to +6 V        |
| VID Pins                            | −0.3 V to +6 V        |
| FBRTN                               | −0.3 V to +0.3 V      |
| SW1 to SW4                          | −5 V to +25 V         |
| All Other Inputs and Outputs        | −0.3 V to VCC + 0.3 V |
| Storage Temperature Range           | −65°C to +150°C       |
| Operating Ambient Temperature Range | 0°C to 85°C           |
| Operating Junction Temperature      | 125°C                 |
| Thermal Impedance ( $\theta_{JA}$ ) | 100°C/W               |
| Lead Temperature                    |                       |
| Soldering (10 sec)                  | 300°C                 |
| Vapor Phase (60 sec)                | 215°C                 |
| Infrared (15 sec)                   | 220°C                 |

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Absolute maximum ratings apply individually only, not in combination. Unless otherwise specified, all other voltages are referenced to GND.

## ESD CAUTION



**ESD (electrostatic discharge) sensitive device.** Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

## PIN CONFIGURATION AND FUNCTION DESCRIPTIONS

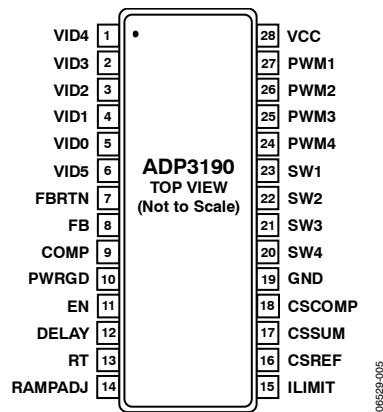


Figure 2. Pin Configuration

Table 3. Pin Function Descriptions

| Pin No.  | Mnemonic           | Description                                                                                                                                                                                                                                                                                                                                                                                      |
|----------|--------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 1 to 6   | VID4 to VID0, VID5 | Voltage Identification DAC Inputs. These six pins are pulled up to an internal reference, providing a Logic 1 if left open. When in normal operation mode, the DAC output programs the FB regulation voltage from 0.8375 V to 1.6 V (see Table 4). Leaving all the VID pins open results in ADP3190 going into a “No CPU” mode, shutting off their PWM outputs and pulling the PWRGD output low. |
| 7        | FBRTN              | Feedback Return. VID DAC and error amplifier reference for remote sensing of the output voltage.                                                                                                                                                                                                                                                                                                 |
| 8        | FB                 | Feedback Input. Error amplifier input for remote sensing of the output voltage. An external resistor between this pin and the output voltage sets the no-load offset point.                                                                                                                                                                                                                      |
| 9        | COMP               | Error Amplifier Output and Compensation Point.                                                                                                                                                                                                                                                                                                                                                   |
| 10       | PWRGD              | Power Good Output. Open drain output that signals when the output voltage is outside of the proper operating range.                                                                                                                                                                                                                                                                              |
| 11       | EN                 | Power Supply Enable Input. Pulling this pin to GND disables the PWM outputs and pulls the PWRGD output low.                                                                                                                                                                                                                                                                                      |
| 12       | DELAY              | Soft Start Delay and Current-Limit Latch-Off Delay Setting Input. An external resistor and capacitor connected between this pin and GND sets the soft start ramp-up time and the overcurrent latch-off delay time.                                                                                                                                                                               |
| 13       | RT                 | Frequency Setting Resistor Input. An external resistor connected between this pin and GND sets the oscillator frequency of the device.                                                                                                                                                                                                                                                           |
| 14       | RAMPADJ            | PWM Ramp Current Input. An external resistor from the converter input voltage to this pin sets the internal PWM ramp.                                                                                                                                                                                                                                                                            |
| 15       | ILIMIT             | Current Limit Set Point/Enable Output. An external resistor from this pin to GND sets the current limit threshold of the converter. This pin is actively pulled low when the ADP3190 EN input is low or when VCC is below its UVLO threshold to signal to the driver IC that the driver high-side and low-side outputs should go low.                                                            |
| 16       | CSREF              | Current Sense Reference Voltage Input. The voltage on this pin is used as the reference for the current sense amplifier and the power-good and crowbar functions. This pin should be connected to the common point of the output inductors.                                                                                                                                                      |
| 17       | CSSUM              | Current Sense Summing Node. External resistors from each switch node to this pin sum the average inductor currents together to measure the total output current.                                                                                                                                                                                                                                 |
| 18       | CSCOMP             | Current Sense Compensation Point. A resistor and capacitor from this pin to CSSUM determine the slope of the load line and the positioning loop response time.                                                                                                                                                                                                                                   |
| 19       | GND                | Ground. All internal biasing and the logic output signals of the device are referenced to this ground.                                                                                                                                                                                                                                                                                           |
| 20 to 23 | SW4 to SW1         | Current Balance Inputs. Inputs for measuring the current level in each phase. The SW pins of unused phases should be left open.                                                                                                                                                                                                                                                                  |
| 24 to 27 | PWM4 to PWM1       | Logic Level PWM Outputs. Each output is connected to the input of an external MOSFET driver, such as the ADP3120A. Connecting the PWM3 and/or PWM4 outputs to GND causes that phase to turn off, allowing the ADP3190 to operate as a 2-, 3-, or 4-phase controller.                                                                                                                             |
| 28       | VCC                | ADP3190: A 240 $\Omega$ resistor should be placed between the 12 V system supply and the VCC pin to ensure 5 V.<br>ADP3190A: A 10 $\Omega$ resistor should be placed between the 5 V system supply and the VCC pin to ensure 5 V.                                                                                                                                                                |

## TYPICAL PERFORMANCE CHARACTERISTICS AND TEST CIRCUITS

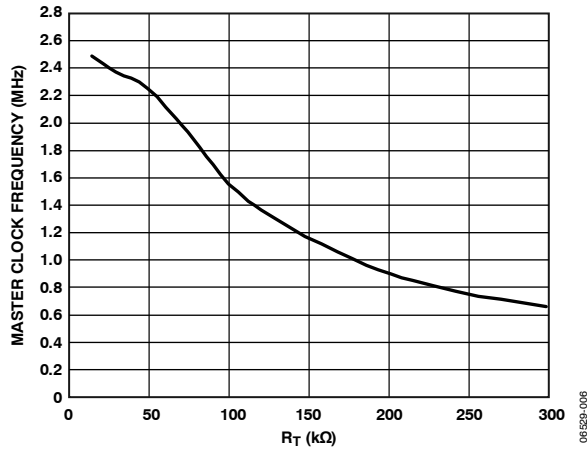


Figure 3. Master Clock Frequency vs.  $R_T$

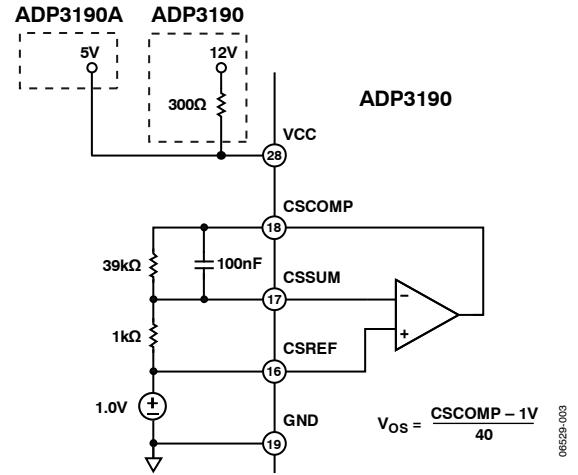


Figure 5. Current Sense Amplifier  $V_{OS}$

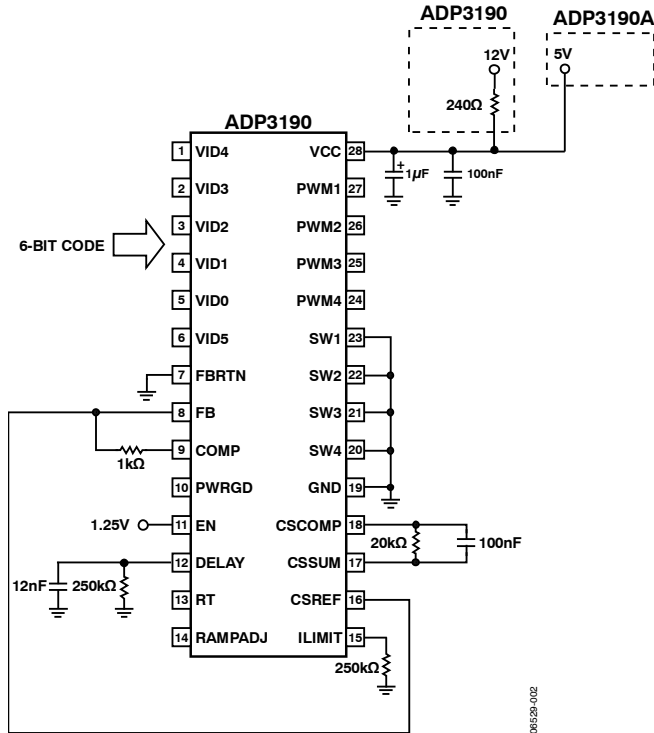


Figure 4. Closed-Loop Output Voltage Accuracy

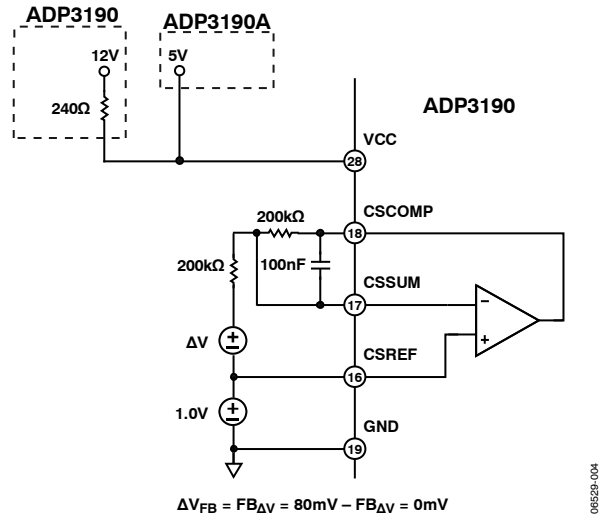


Figure 6. Positioning Voltage

## THEORY OF OPERATION

The ADP3190 combines a multimode, fixed frequency PWM control with multiphase logic outputs for use in 2-/3-/4-phase synchronous buck CPU core supply power converters. The internal VID DAC is designed to interface with the Intel 6-bit VRD/VRM 10- and 10.1-compatible CPUs. Multiphase operation is important for producing the high currents and low voltages demanded by today's microprocessors. Handling the high currents in a single-phase converter places high thermal demands on the components in the system, such as the inductors and MOSFETs.

The multimode control of the ADP3190 ensures a stable, high performance topology for

- Balancing currents and thermals between phases
- High speed response at the lowest possible switching frequency and output decoupling
- Minimizing thermal switching losses due to lower frequency operation
- Tight load line regulation and accuracy
- High current output for up to 4-phase operation
- Reduced output ripple due to multiphase cancellation
- PC board layout noise immunity
- Ease of use and design due to independent component selection
- Flexibility in operation for tailoring design to low cost or high performance

### STARTUP SEQUENCE

During startup, the number of operational phases and their phase relationship is determined by the internal circuitry that monitors the PWM outputs. Normally, the ADP3190 operates as a 4-phase PWM controller. Grounding the PWM4 pin programs 3-phase operation, while grounding the PWM3 pin and the PWM4 pin programs 2-phase operation.

When the ADP3190 is enabled, the controller outputs a voltage on PWM3 and PWM4, which is approximately 675 mV. An internal comparator checks each pin's voltage vs. a threshold of 300 mV. If the pin is grounded, it is below the threshold, and the phase is disabled. The output resistance of the PWM pins is approximately 5 k $\Omega$  during this detection time. To ensure proper operation, any external pull-down resistance connected to the PWM pins should not be less than 25 k $\Omega$ . PWM1 and PWM2 are disabled during the phase detection interval, which occurs during the first two clock cycles of the internal oscillator.

After this time, if the PWM output is not grounded, the 5 k $\Omega$  resistance is removed, and it switches between 0 V and 5 V.

If the PWM output is grounded, it remains off. The PWM outputs are logic-level devices intended for driving external gate drivers, such as the ADP3120A. Because each phase is monitored independently, operation approaching 100% duty cycle is possible. Also, more than one output can be on at the same time for overlapping phases.

### MASTER CLOCK FREQUENCY

The clock frequency of the ADP3190 is set with an external resistor connected from the RT pin to ground. The frequency follows the graph in Figure 3. To determine the frequency per phase, the clock is divided by the number of phases in use. If PWM4 is grounded, divide the master clock by 3 for the frequency of the remaining phases. If PWM3 and PWM4 are grounded, divide by 2. If all phases are in use, divide by 4.

### OUTPUT VOLTAGE DIFFERENTIAL SENSING

The ADP3190 differential sense compares a high accuracy VID DAC and a precision reference to implement a low offset error amplifier. This maintains a worst-case specification of  $\pm 9.5$  mV differential sensing error over their full operating output voltage and temperature range. The output voltage is sensed between the FB pin and the FBRTN pin. FB should be connected through a resistor to the regulation point, usually the remote sense pin of the microprocessor. FBRTN should be connected directly to the remote sense ground point. The internal VID DAC and precision reference are referenced to FBRTN, which has a minimal current of 100  $\mu$ A to allow accurate remote sensing. The internal error amplifier compares the output of the DAC to the FB pin to regulate the output voltage.

### OUTPUT CURRENT SENSING

The ADP3190 provides a dedicated current sense amplifier (CSA) to monitor the total output current for proper voltage positioning vs. load current and for current-limit detection. Sensing the load current at the output gives the total average current being delivered to the load, which is an inherently more accurate method than peak current detection or sampling the current across a sense element, such as the low-side MOSFET. This amplifier can be configured in the following ways, depending on the objectives of the system:

- Output inductor DCR sensing without a thermistor for lowest cost
- Output inductor DCR sensing with a thermistor for improved accuracy with tracking of inductor temperature
- Sense resistors for highest accuracy measurements



The positive input of the CSA is connected to the CSREF pin, which is connected to the output voltage. The inputs to the amplifier are summed together through resistors from the sensing element (such as the switch node side of the output inductors) to the inverting input, CSSUM. The feedback resistor between CSCOMP and CSSUM sets the gain of the amplifier, and a filter capacitor is placed in parallel with this resistor. The gain of the amplifier is programmable by adjusting the feedback resistor to set the load line required by the microprocessor. The current information is then given as the difference of CSREF – CSCOMP. This difference signal is used internally to offset the VID DAC for voltage positioning and as a differential input for the current-limit comparator.

To provide the best accuracy for sensing current, the CSA is designed to have a low offset input voltage. In addition, the sensing gain is determined by external resistors, so it can be made extremely accurate.

### ACTIVE IMPEDANCE CONTROL MODE

For controlling the dynamic output voltage droop as a function of output current, a signal proportional to the total output current at the CSCOMP pin can be scaled to equal the droop impedance of the regulator multiplied by the output current. This droop voltage is then used to set the input control voltage to the system. The droop voltage is directly subtracted from the DAC reference input voltage to tell the error amplifier where the output voltage should be. This differs from previous implementations and allows enhanced feed-forward response.

### CURRENT-CONTROL MODE AND THERMAL BALANCE

The ADP3190 has individual inputs for each phase, which are used for monitoring the current in each phase. This information is combined with an internal ramp to create a current balancing feedback system, which has been optimized for initial current balance accuracy and dynamic thermal balancing during operation. This current-balance information is independent of the average output current information used for positioning described previously.

The magnitude of the internal ramp can be set to optimize the transient response of the system. It also monitors the supply voltage for feed-forward control for changes in the supply. A resistor connected from the power input voltage to the RAMPADJ pin determines the slope of the internal PWM ramp. Detailed information about programming the ramp is given in the Application Information section.

External resistors can be placed in series with individual phases to create, if desired, an intentional current imbalance such as when one phase may have better cooling and can support higher currents. Resistor  $R_{SW1}$  through Resistor  $R_{SW4}$  (see the typical application circuit in Figure 9) can be used for adjusting thermal balance. It is best to have the ability to add these resistors during the initial design, so placeholders should be provided in the layout.

To increase the current in any given phase, make  $R_{SW}$  for this phase larger (make  $R_{SW} = 0$  for the hottest phase; do not change during balancing). Increasing  $R_{SW}$  to only 500  $\Omega$  makes a substantial increase in phase current. Increase each  $R_{SW}$  value by small amounts to achieve balance, starting with the coolest phase first.

### VOLTAGE CONTROL MODE

A high gain bandwidth voltage-mode error amplifier is used for the voltage-mode control loop. The control input voltage to the positive input is set via the VID logic according to the voltages listed in Table 4. This voltage is also offset by the droop voltage for active positioning of the output voltage as a function of current, commonly known as active voltage positioning. The output of the amplifier is the COMP pin, which sets the termination voltage for the internal PWM ramps.

The negative input (FB) is tied to the output sense location with a resistor ( $R_B$ ) and is used for sensing and controlling the output voltage at this point. A current source from the FB pin flowing through  $R_B$  is used for setting the no-load offset voltage from the VID voltage. The no-load voltage is negative with respect to the VID DAC. The main loop compensation is incorporated into the feedback network between FB and COMP.

### SOFT START

The power-on ramp-up time of the output voltage is set with a capacitor and resistor in parallel from the DELAY pin to ground. The RC time constant also determines the current-limit latch-off time. In UVLO, or when EN is a logic low, the DELAY pin is held at ground. After the UVLO threshold is reached and EN is a logic high, the DELAY capacitor is charged with an internal 20  $\mu$ A current source. The output voltage follows the ramping voltage on the DELAY pin, limiting the inrush current. The soft start time depends on the value of the VID DAC and  $C_{DLY}$ , with a secondary effect from  $R_{DLY}$ . Refer to the Application Information section for detailed information on setting  $C_{DLY}$ .

If EN is taken low or if VCC drops below UVLO, the DELAY capacitor is reset to ground to be ready for another soft start cycle. Figure 7 shows a typical soft start sequence for the ADP3190.

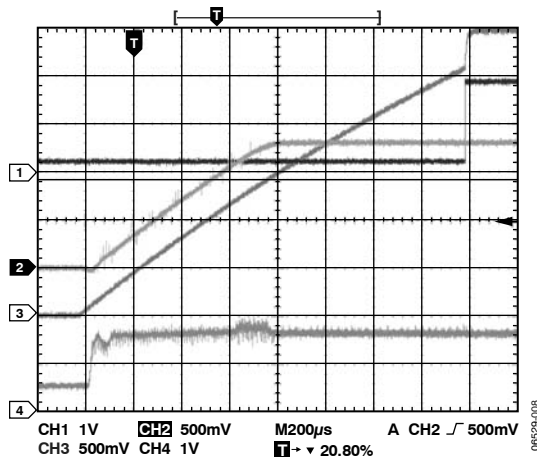


Figure 7. Typical Start-Up Waveforms;  
Channel 1: PWRGD, Channel 2: CSREF,  
Channel 3: DELAY, Channel 4: COMP

## CURRENT-LIMIT, SHORT-CIRCUIT, AND LATCH-OFF PROTECTION

The ADP3190 compares a programmable current-limit setpoint to the voltage from the output of the current sense amplifier. The level of current limit is set with the resistor from the ILIMIT pin to ground. During normal operation, the voltage on ILIMIT is 3 V. The current through the external resistor is internally scaled to give a current-limit threshold of 10.4 mV/μA. If the difference in voltage between CSREF and CSCOMP rises above the current-limit threshold, the internal current-limit amplifier controls the internal COMP voltage to maintain the average output current at the limit.

After the limit is reached, the 3 V pull-up on the DELAY pin is disconnected, and the external delay capacitor is discharged through the external resistor. A comparator monitors the DELAY voltage and shuts off the controller when the voltage drops below 1.8 V. The current-limit latch-off delay time is therefore set by the RC time constant discharging from 3 V to 1.8 V. The Application Information section discusses the selection of  $C_{DLY}$  and  $R_{DLY}$ .

Because the controller continues to cycle the phases during the latch-off delay time, the controller returns to normal operation if the short is removed before the 1.8 V threshold is reached. The recovery characteristic depends on the state of PWRGD. If the output voltage is within the PWRGD window, the controller resumes normal operation. However, if a short circuit has caused the output voltage to drop below the PWRGD threshold, a soft start cycle is initiated.

The latch-off function can be reset either by removing and reapplying VCC to the ADP3190 or by pulling the EN pin low for a short time. To disable the short-circuit latch-off function, the external resistor to ground should be left open, and a high value ( $>1\text{ M}\Omega$ ) resistor should be connected from DELAY to VCC.

This prevents the DELAY capacitor from discharging, so the 1.8 V threshold is never reached. The resistor has an impact on the soft start time because the current through it adds to the internal 20 μA current source.

During startup, when the output voltage is below 200 mV, a secondary current limit is active. This is necessary because the voltage swing of CSCOMP cannot go below ground. This secondary current limit controls the internal COMP voltage to the PWM comparators to 2 V. This limits the voltage drop across the low-side MOSFETs through the current balance circuitry.

An inherent per phase current limit protects individual phases, if one or more phases stop functioning because of a faulty component. This limit is based on the maximum normal mode COMP voltage.

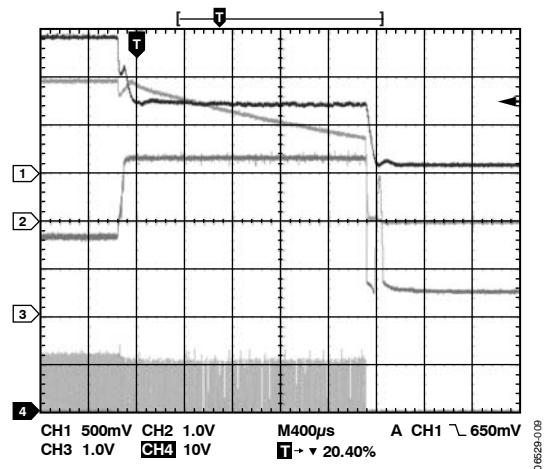


Figure 8. Overcurrent Latch-Off Waveforms;  
Channel 1: CSREF, Channel 2: DELAY,  
Channel 3: COMP, Channel 4: Phase 1 Switch Node

## DYNAMIC VID

The ADP3190 has the ability to dynamically change the VID input while the controller is running. This allows the output voltage to change while the supply is running and supplying current to the load. This is commonly referred to as VID on-the-fly (OTF). A VID OTF can occur under either light or heavy load conditions. The processor signals the controller by changing the VID inputs in multiple steps from the start code to the finish code. This change can be positive or negative.

When a VID input changes state, the ADP3190 detects the change and ignore the DAC inputs for a minimum of 400 ns. This time prevents a false code due to logic skew while the six VID inputs are changing. Additionally, the first VID change initiates the PWRGD and crowbar blanking functions for a minimum of 100 μs to prevent a false PWRGD or crowbar event. Each VID change resets the internal timer.

Table 4. VID Codes for the ADP3190

| VID4 | VID3 | VID2 | VID1 | VID0 | VID5 | Output   | VID4 | VID3 | VID2 | VID1 | VID0 | VID5 | Output   |
|------|------|------|------|------|------|----------|------|------|------|------|------|------|----------|
| 1    | 1    | 1    | 1    | 1    | 1    | No CPU   | 1    | 1    | 0    | 1    | 0    | 0    | 1.2125 V |
| 1    | 1    | 1    | 1    | 1    | 0    | No CPU   | 1    | 1    | 0    | 0    | 1    | 1    | 1.2250 V |
| 0    | 1    | 0    | 1    | 0    | 0    | 0.8375 V | 1    | 1    | 0    | 0    | 1    | 0    | 1.2375 V |
| 0    | 1    | 0    | 0    | 1    | 1    | 0.8500 V | 1    | 1    | 0    | 0    | 0    | 1    | 1.2500 V |
| 0    | 1    | 0    | 0    | 1    | 0    | 0.8625 V | 1    | 1    | 0    | 0    | 0    | 0    | 1.2625 V |
| 0    | 1    | 0    | 0    | 0    | 1    | 0.8750 V | 1    | 0    | 1    | 1    | 1    | 1    | 1.2750 V |
| 0    | 1    | 0    | 0    | 0    | 0    | 0.8875 V | 1    | 0    | 1    | 1    | 1    | 0    | 1.2875 V |
| 0    | 0    | 1    | 1    | 1    | 1    | 0.9000 V | 1    | 0    | 1    | 1    | 0    | 1    | 1.3000 V |
| 0    | 0    | 1    | 1    | 1    | 0    | 0.9125 V | 1    | 0    | 1    | 1    | 0    | 0    | 1.3125 V |
| 0    | 0    | 1    | 1    | 0    | 1    | 0.9250 V | 1    | 0    | 1    | 0    | 1    | 1    | 1.3250 V |
| 0    | 0    | 1    | 1    | 0    | 0    | 0.9375 V | 1    | 0    | 1    | 0    | 1    | 0    | 1.3375 V |
| 0    | 0    | 1    | 0    | 1    | 1    | 0.9500 V | 1    | 0    | 1    | 0    | 0    | 1    | 1.3500 V |
| 0    | 0    | 1    | 0    | 1    | 0    | 0.9625 V | 1    | 0    | 1    | 0    | 0    | 0    | 1.3625 V |
| 0    | 0    | 1    | 0    | 0    | 1    | 0.9750 V | 1    | 0    | 0    | 1    | 1    | 1    | 1.3750 V |
| 0    | 0    | 1    | 0    | 0    | 0    | 0.9875 V | 1    | 0    | 0    | 1    | 1    | 0    | 1.3875 V |
| 0    | 0    | 0    | 1    | 1    | 1    | 1.0000 V | 1    | 0    | 0    | 1    | 0    | 1    | 1.4000 V |
| 0    | 0    | 0    | 1    | 1    | 0    | 1.0125 V | 1    | 0    | 0    | 1    | 0    | 0    | 1.4125 V |
| 0    | 0    | 0    | 1    | 0    | 1    | 1.0250 V | 1    | 0    | 0    | 0    | 1    | 1    | 1.4250 V |
| 0    | 0    | 0    | 1    | 0    | 0    | 1.0375 V | 1    | 0    | 0    | 0    | 1    | 0    | 1.4375 V |
| 0    | 0    | 0    | 0    | 1    | 1    | 1.0500 V | 1    | 0    | 0    | 0    | 0    | 1    | 1.4500 V |
| 0    | 0    | 0    | 0    | 1    | 0    | 1.0625 V | 1    | 0    | 0    | 0    | 0    | 0    | 1.4625 V |
| 0    | 0    | 0    | 0    | 0    | 1    | 1.0750 V | 0    | 1    | 1    | 1    | 1    | 1    | 1.4750 V |
| 0    | 0    | 0    | 0    | 0    | 0    | 1.0875 V | 0    | 1    | 1    | 1    | 1    | 0    | 1.4875 V |
| 1    | 1    | 1    | 1    | 0    | 1    | 1.1000 V | 0    | 1    | 1    | 1    | 0    | 1    | 1.5000 V |
| 1    | 1    | 1    | 1    | 0    | 0    | 1.1125 V | 0    | 1    | 1    | 1    | 0    | 0    | 1.5125 V |
| 1    | 1    | 1    | 0    | 1    | 1    | 1.1250 V | 0    | 1    | 1    | 0    | 1    | 1    | 1.5250 V |
| 1    | 1    | 1    | 0    | 1    | 0    | 1.1375 V | 0    | 1    | 1    | 0    | 1    | 0    | 1.5375 V |
| 1    | 1    | 1    | 0    | 0    | 1    | 1.1500 V | 0    | 1    | 1    | 0    | 0    | 1    | 1.5500 V |
| 1    | 1    | 1    | 0    | 0    | 0    | 1.1625 V | 0    | 1    | 1    | 0    | 0    | 0    | 1.5625 V |
| 1    | 1    | 0    | 1    | 1    | 1    | 1.1750 V | 0    | 1    | 0    | 1    | 1    | 1    | 1.5750 V |
| 1    | 1    | 0    | 1    | 1    | 0    | 1.1875 V | 0    | 1    | 0    | 1    | 1    | 0    | 1.5875 V |
| 1    | 1    | 0    | 1    | 0    | 1    | 1.2000 V | 0    | 1    | 0    | 1    | 0    | 1    | 1.6000 V |

## POWER-GOOD MONITORING

The power-good comparator monitors the output voltage via the CSREF pin. The PWRGD pin is an open-drain output whose high level (when connected to a pull-up resistor) indicates that the output voltage is within the nominal limits specified in Table 4. These limits are based on the VID voltage setting. PWRGD goes low if the output voltage is outside of this specified range, if all of the VID DAC inputs are high, or whenever the EN pin is pulled low. PWRGD is blanked during a VID OTF event for a period of 250  $\mu$ s to prevent false signals during the time the output is changing.

The PWRGD circuitry also incorporates an initial turn-on delay time based on the DELAY ramp. The PWRGD pin is held low until the DELAY pin reaches 2.6 V. The time between when the PWRGD undervoltage threshold is reached and when the DELAY pin reaches 2.6 V provides the turn-on delay time. This time is incorporated into the soft start ramp. To ensure a 1 ms delay time on PWRGD, the soft start ramp must also be  $>1$  ms. Refer to the Application Information section for detailed information on setting  $C_{DLY}$ .

## OUTPUT CROWBAR

As part of the protection for the load and output components of the supply, the PWM outputs are driven low (turning on the low-side MOSFETs) when the output voltage exceeds the upper

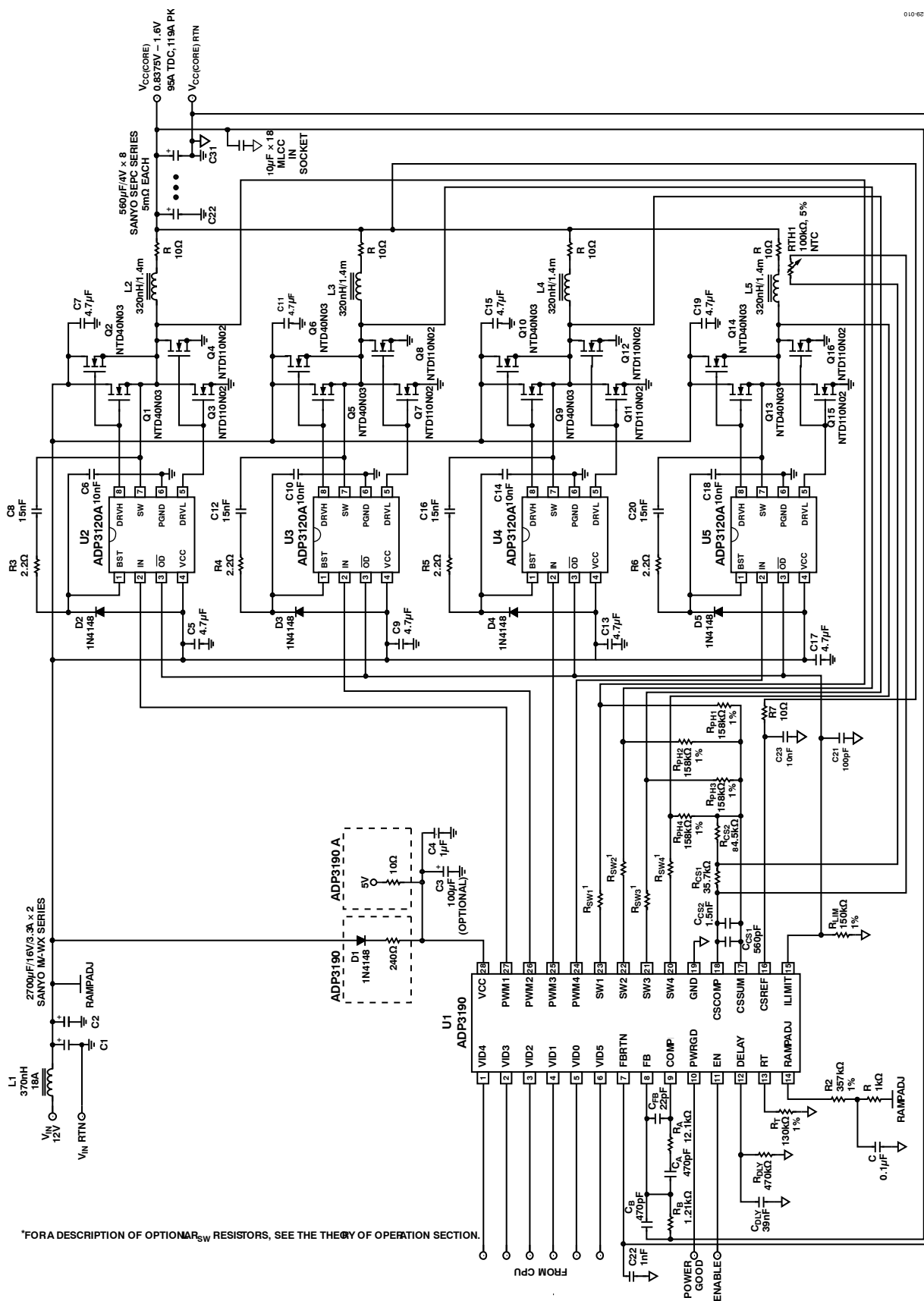
crowbar threshold. This crowbar action stops once the output voltage falls below the release threshold of approximately 550 mV.

Turning on the low-side MOSFETs pulls down the output as the reverse current builds up in the inductors. If the output over-voltage is due to a short in the high-side MOSFET, this action current-limits the input supply or blows its fuse, protecting the microprocessor from being destroyed.

## OUTPUT ENABLE AND UVLO

For the ADP3190 to begin switching, the input supply (VCC) to the controller must be higher than the UVLO threshold, and the EN pin must be higher than its logic threshold. If UVLO is less than the threshold or the EN pin is a logic low, the ADP3190 is disabled. This holds the PWM outputs at ground, shorts the DELAY capacitor to ground, and holds the ILIMIT pin at ground.

In the application circuit, the ILIMIT pin should be connected to the  $\overline{OD}$  pins of the ADP3120A drivers. The ILIMIT being grounded disables the drivers so that both the DRVH and DRVL are grounded. This feature is important in preventing the discharge of the output capacitors when the controller is shut off. If the driver outputs are not disabled, a negative voltage could be generated during output due to the high current discharge of the output capacitors through the inductors.



## APPLICATION INFORMATION

The design parameters for a typical Intel VRD 10.1-compliant CPU application are as follows:

- Input voltage ( $V_{IN}$ ) = 12 V
- VID setting voltage ( $V_{VID}$ ) = 1.300 V
- Duty cycle (D) = 0.108
- Nominal output voltage at no load ( $V_{ONL}$ ) = 1.281 V
- Nominal output voltage at 101 A load ( $V_{OFL}$ ) = 1.180 V
- Static output voltage drop based on a 1.0 mΩ load line ( $R_O$ ) from no load to full load ( $V_D$ ) =  $V_{ONL} - V_{OFL} = 1.281 \text{ V} - 1.180 \text{ V} = 101 \text{ mV}$
- Maximum output current ( $I_O$ ) = 119 A
- Maximum output current step ( $\Delta I_O$ ) = 95 A
- Number of phases (n) = 4
- Switching frequency per phase ( $f_{SW}$ ) = 330 kHz

### SETTING THE CLOCK FREQUENCY

The ADP3190 uses a fixed-frequency control architecture. The frequency is set by an external timing resistor ( $R_T$ ). The clock frequency and the number of phases determine the switching frequency per phase, which directly relates to switching losses and the sizes of the inductors and/or the input and output capacitors. With  $n = 4$  for four phases, a clock frequency of 1.32 MHz sets the switching frequency ( $f_{SW}$ ) of each phase to 330 kHz, which represents a practical trade-off between the switching losses and the sizes of the output filter components. Figure 3 shows that to achieve 1.32 MHz oscillator frequency, the correct value for  $R_T$  is 130 kΩ. Alternatively, the value for  $R_T$  can be calculated using

$$R_T = \frac{1}{n \times f_{SW} \times 4.7 \text{ pF}} - 31 \text{ k}\Omega \quad (1)$$

where 4.7 pF and 31 kΩ are internal IC component values. For good initial accuracy and frequency stability, a 1% resistor is recommended.

### SOFT START AND CURRENT-LIMIT LATCH-OFF DELAY TIMES

Because the soft start and current-limit latch-off delay functions share the DELAY pin, these two parameters must be considered together. The first step is to set  $C_{DLY}$  for the soft start ramp. This ramp is generated with a 20 μA internal current source. The value of  $R_{DLY}$  has a second-order impact on the soft start time because it sinks part of the current source to ground.

However, as long as  $R_{DLY}$  is kept greater than 200 kΩ, this effect is minor. The value for  $C_{DLY}$  can be approximated using

$$C_{DLY} = \left( 20 \mu\text{A} - \frac{V_{VID}}{2 \times R_{DLY}} \right) \times \frac{t_{SS}}{V_{VID}} \quad (2)$$

where  $t_{SS}$  is the desired soft start time.

Assuming an  $R_{DLY}$  of 390 kΩ and a desired soft start time of 3 ms,  $C_{DLY}$  is 36 nF. The closest standard value for  $C_{DLY}$  is 39 nF. Once  $C_{DLY}$  is chosen,  $R_{DLY}$  can be calculated for the current-limit latch-off time using

$$R_{DLY} = \frac{1.96 \times t_{DELAY}}{C_{DLY}} \quad (3)$$

If the result for  $R_{DLY}$  is less than 200 kΩ, a smaller soft start time should be considered by recalculating the equation for  $C_{DLY}$ , or a longer latch-off time should be used.  $R_{DLY}$  should never be less than 200 kΩ. In this example, a delay time of 9 ms results in  $R_{DLY} = 452 \text{ k}\Omega$ . The closest standard 5% value is 470 kΩ.

### INDUCTOR SELECTION

The choice of inductance for the inductor determines the ripple current in the inductor. Less inductance leads to more ripple current, which increases the output ripple voltage and conduction losses in the MOSFETs, but it allows using smaller inductors and, for a specified peak-to-peak transient deviation, less total output capacitance.

Conversely, a higher inductance means lower ripple current and reduced conduction losses but requires larger inductors and more output capacitance for the same peak-to-peak transient deviation. In any multiphase converter, a practical value for the peak-to-peak inductor ripple current is less than 50% of the maximum dc current in the same inductor. Equation 4 shows the relationship between the inductance, oscillator frequency, and peak-to-peak ripple current in the inductor.

$$I_R = \frac{V_{VID} \times (1 - D)}{f_{SW} \times L} \quad (4)$$

Equation 5 can be used to determine the minimum inductance based on a given output ripple voltage.

$$L \geq \frac{V_{VID} \times R_O \times (1 - (n \times D))}{f_{SW} \times V_{RIPPLE}} \quad (5)$$

Solving Equation 5 for a 10 mV p-p output ripple voltage yields

$$L \geq \frac{1.3 \text{ V} \times 1.0 \text{ m}\Omega \times (1 - 0.432)}{330 \text{ kHz} \times 10 \text{ mV}} = 224 \text{ nH}$$

If the resulting ripple voltage is less than it is designed for, make the inductor smaller until the ripple value is met.



This allows optimal transient response and minimum output decoupling.

The smallest possible inductor should be used to minimize the number of output capacitors. For this example, choosing a 320 nH inductor is a good starting point and gives a calculated ripple current of 11 A. The inductor should not saturate at the peak current of 35.5 A and should be able to handle the sum of the power dissipation caused by the average current of 30 A in the winding and core loss.

Another important factor in the inductor design is the DCR, which is used for measuring the phase currents. A large DCR can cause excessive power losses, while too small a value can lead to increased measurement error. A good rule is to have the DCR be about 1 to 1½ times the droop resistance ( $R_O$ ). For this design, an inductor with a DCR of 1.4 mΩ is used.

## DESIGNING AN INDUCTOR

Once the inductance and DCR are known, the next step is to either design an inductor or find a standard inductor that comes as close as possible to meeting the overall design goals. It is also important to have the inductance and DCR tolerance specified to control the accuracy of the system. Reasonable tolerances most manufacturers can meet are 15% inductance and 8% DCR (at room temperature).

The first decision in designing the inductor is to choose the core material. Several possibilities for providing low core loss at high frequencies include the powder cores (for example, Kool Mμ® from Magnetics, Inc.) and the gapped soft ferrite cores (for example, 3F3 or 3F4 from Philips). Low frequency powdered iron cores should be avoided due to their high core loss, especially when the inductor value is relatively low and the ripple current is high.

The best choice for a core geometry is a closed-loop type such as a potentiometer core, PQ, U, or E core or toroid. A good compromise between price and performance is a core with a toroidal shape.

Many useful magnetics design references are available for quickly designing a power inductor, such as

- Magnetic Designer Software, Intusoft
- *Designing Magnetic Components for High-Frequency DC-DC Converters*, by William T. McLyman, KG Magnetics, Inc., ISBN 1883107008

## Selecting a Standard Inductor

The following power inductor manufacturers can provide design consultation and deliver power inductors optimized for high power applications upon request:

- Coilcraft
- Coiltronics
- Sumida Electric Company
- Vishay Intertechnology

## OUTPUT DROOP RESISTANCE

The design requires the regulator output voltage measured at the CPU pins to drop when the output current increases. The specified voltage drop corresponds to a dc output resistance ( $R_O$ ).

The output current is measured by summing the voltage across each inductor and passing the signal through a low-pass filter. This summer filter is the CS amplifier configured with  $R_{PH(X)}$  (summers),  $R_{CS}$ , and  $C_{CS}$  (filter). The output resistance of the regulator is set by the following equations, where  $R_L$  is the DCR of the output inductors:

$$R_O = \frac{R_{CS}}{R_{PH(X)}} \times R_L \quad (6)$$

$$C_{CS} = \frac{L}{R_L \times R_{CS}} \quad (7)$$

The user has the flexibility of choosing either  $R_{CS}$  or  $R_{PH(X)}$ . It is best to select  $R_{CS}$  equal to 100 kΩ, and then solve for  $R_{PH(X)}$  by rearranging Equation 6.

$$R_{PH(X)} = \frac{R_L}{R_O} \times R_{CS}$$

$$R_{PH(X)} = \frac{1.4 \text{ m}\Omega}{1.0 \text{ m}\Omega} \times 100 \text{ k}\Omega = 140 \text{ k}\Omega$$

Next, use Equation 6 to solve for  $C_{CS}$ .

$$C_{CS} = \frac{320 \text{ nH}}{1.4 \text{ m}\Omega \times 100 \text{ k}\Omega} = 2.28 \text{ nF}$$

It is best to have a dual location for  $C_{CS}$  in the layout so that standard values can be used in parallel to get as close as possible to the value desired. For accuracy,  $C_{CS}$  should be a 5% or 10% NPO capacitor. This example uses a 5% combination for  $C_{CS}$  of 1.5 nF and 560 pF in parallel. Recalculating  $R_{CS}$  and  $R_{PH(X)}$  using this capacitor combination yields 110 kΩ and 154 kΩ. The closest standard 1% value for  $R_{PH(X)}$  is 158 kΩ.

## INDUCTOR DCR TEMPERATURE CORRECTION

With the inductor's DCR being used as the sense element and copper wire being the source of the DCR, compensation is needed for temperature changes of the inductor's winding. Fortunately, copper has a well-known temperature coefficient (TC) of 0.39%/°C.

If  $R_{CS}$  is designed to have an opposite and equal percentage change in resistance to that of the wire, it cancels the temperature variation of the inductor's DCR. Due to the nonlinear nature of NTC thermistors, Resistor  $R_{CS1}$  and Resistor  $R_{CS2}$  are needed. Figure 10 shows how to linearize the NTC and produce the desired temperature tracking.

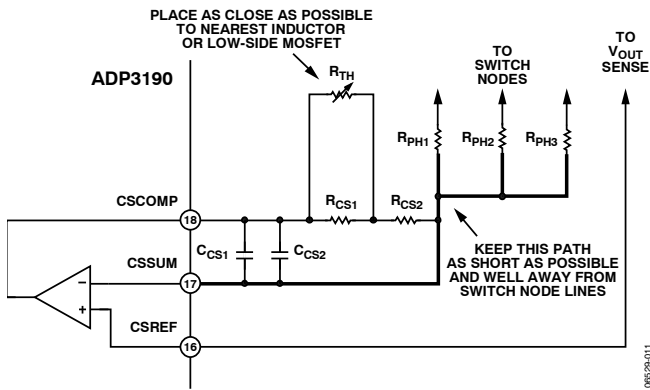


Figure 10. Temperature Compensation Circuit Values

The following procedure and expressions yield values to use for  $R_{CS1}$ ,  $R_{CS2}$ , and  $R_{TH}$  (the thermistor value at 25°C) for a given  $R_{CS}$  value:

1. Select an NTC based on type and value. Because there is not a value yet, start with a thermistor with a value close to  $R_{CS}$ . The NTC should also have an initial tolerance of better than 5%.
2. Based on the type of NTC, find its relative resistance value at two temperatures. The temperatures that work well are 50°C and 90°C. These resistance values are called  $A$  ( $R_{TH(50°C)}/R_{TH(25°C)}$ ) and  $B$  ( $R_{TH(90°C)}/R_{TH(25°C)}$ ). The NTC's relative value is always 1 at 25°C.
3. Find the relative values of  $R_{CS}$  required for each of these temperatures. This is based on the percentage change needed, which in this example is initially 0.39%/°C. These are called  $r_1$  ( $1/[1 + TC \times (T_1 - 25)]$ ) and  $r_2$  ( $1/[1 + TC \times (T_2 - 25)]$ ), where  $TC = 0.0039$  for copper.  $T_1 = 50°C$  and  $T_2 = 90°C$  are chosen. From this, calculate that  $r_1 = 0.9112$  and  $r_2 = 0.7978$ .

4. Compute the relative values for  $r_{CS1}$ ,  $r_{CS2}$ , and  $r_{TH}$  using

$$r_{CS2} = \frac{(A - B) \times r_1 \times r_2 - A \times (1 - B) \times r_2 + B \times (1 - A) \times r_1}{A \times (1 - B) \times r_1 - B \times (1 - A) \times r_2 - (A - B)}$$

$$r_{CS1} = \frac{(1 - A)}{\frac{1}{1 - r_{CS2}} - \frac{A}{r_1 - r_{CS2}}}$$

$$r_{TH} = \frac{1}{\frac{1}{1 - r_{CS2}} - \frac{1}{r_{CS1}}} \quad (8)$$

5. Calculate  $R_{TH} = r_{TH} \times R_{CS}$ , then select the closest value of thermistor available. Also, compute a scaling factor  $k$  based on the ratio of the actual thermistor value used relative to the computed one:

$$k = \frac{R_{TH(ACTUAL)}}{R_{TH(CALCULATED)}} \quad (9)$$

6. Calculate values for  $R_{CS1}$  and  $R_{CS2}$  using Equation 10.

$$R_{CS1} = R_{CS} \times k \times r_{CS1}$$

$$R_{CS2} = R_{CS} \times ((1 - k) + (k \times r_{CS2})) \quad (10)$$

For this example,  $R_{CS}$  has been calculated to be 110 kΩ. Start with a thermistor value of 100 kΩ. Next, look through the available 0603-size thermistors, and find a Vishay NTHS0603N01N1003JR NTC thermistor with  $A = 0.3602$  and  $B = 0.09174$ . From these, compute  $R_{CS1} = 0.3795$ ,  $R_{CS2} = 0.7195$ , and  $R_{TH} = 1.075$ . Solve for  $R_{TH}$ , which yields 118.28 kΩ. Then, choose 100 kΩ, which makes  $k = 0.8455$ . Finally,  $R_{CS1}$  and  $R_{CS2}$  are 35.3 kΩ and 83.9 kΩ. Choose the closest 1% resistor values, which yields a choice of 35.7 kΩ or 84.5 kΩ.

## OUTPUT OFFSET

The Intel specification requires that at no load should the nominal output voltage of the regulator be offset to a value lower than the nominal voltage corresponding to the VID code. The offset is set by a constant current source flowing out of the FB pin ( $I_{FB}$ ) and flowing through  $R_B$ . The value of  $R_B$  can be found using Equation 11.

$$R_B = \frac{V_{VID} - V_{ONL}}{I_{FB}}$$

$$R_B = \frac{1.3 \text{ V} - 1.281 \text{ V}}{15.5 \mu\text{A}} = 1.22 \text{ k}\Omega \quad (11)$$

The closest standard 1% resistor value is 1.21 kΩ.



## C<sub>OUT</sub> SELECTION

The required output decoupling for the regulator is typically recommended by Intel for various processors and platforms. Also, to determine what is required, use some simple design guidelines that are based on having both bulk and ceramic capacitors in the system.

The first thing is to select the total amount of ceramic capacitance. This is based on the number and type of capacitor to be used. The best location for ceramic capacitors is inside the socket, with 12 to 18 of size 1206 being the physical limit. Additional ceramic capacitors can be placed along the outer edge of the socket as well.

Combined ceramic values of 200 µF to 300 µF are recommended, usually made up of multiple 10 µF or 22 µF capacitors. Select the number of ceramic capacitors, and find the total ceramic capacitance (C<sub>Z</sub>).

Next, there is an upper limit imposed on the total amount of bulk capacitance (C<sub>X</sub>) when considering the VID on-the-fly voltage stepping of the output (voltage step, V<sub>V</sub>, in time, t<sub>V</sub>, with error of V<sub>ERR</sub>). A lower limit is based on meeting the capacitance for load release for a given maximum load step, ΔI<sub>O</sub>, and a maximum allowable overshoot. The total amount of load release voltage is given as

$$\Delta V_O = \Delta I_O \times R_O + \Delta V_{RL}$$

where ΔV<sub>rl</sub> is the maximum allowable overshoot voltage.

$$C_{x(MIN)} \geq \left( \frac{L \times \Delta I_O}{n \times \left( R_O + \frac{\Delta V_{RL}}{\Delta I_O} \right) \times V_{VID}} - C_z \right) \quad (12)$$

$$C_{x(MAX)} \leq \frac{L}{nK^2 R_O^2} \times \frac{V_V}{V_{VID}} \times \left( \sqrt{1 + \left( t_V \frac{V_{VID}}{V_V} \times \frac{nKR_O}{L} \right)^2} - 1 \right) - C_z \quad (13)$$

$$\text{where } K = \ln \left( \frac{V_{ERR}}{V_V} \right).$$

To meet the conditions of these expressions and transient response, the ESR of the bulk capacitor bank (R<sub>X</sub>) should be less than two times the droop resistance (R<sub>O</sub>). If the C<sub>X(MIN)</sub> is larger than C<sub>X(MAX)</sub>, the system cannot meet the VID on-the-fly specification and may require the use of a smaller inductor or more phases (and may need the switching frequency to increase to keep the output ripple the same).

The following example uses 18, 10 µF 1206 MLC capacitors (C<sub>Z</sub> = 180 µF). The VID on-the-fly step change is 450 mV in 230 µs with a settling error of 2.5 mV. The maximum allowable load release overshoot for this example is 50 mV, so solving for the bulk capacitance yields

$$C_{x(MIN)} \leq \left( \frac{320 \text{ nH} \times 95 \text{ A}}{4 \times \left( 1.0 \text{ m}\Omega + \frac{50 \text{ mV}}{95 \text{ A}} \right) \times 1.3 \text{ V}} - 180 \text{ }\mu\text{F} \right) = 3.65 \text{ mF}$$

$$C_{x(MAX)} \leq \frac{320 \text{ nH} \times 450 \text{ mV}}{4 \times 4.6^2 \times (1.0 \text{ m}\Omega)^2 \times 1.3 \text{ V}} \times \left( \sqrt{1 + \left( \frac{230 \text{ }\mu\text{s} \times 1.3 \text{ V} \times 4 \times 4.6 \times 1.0 \text{ m}\Omega}{450 \text{ mV} \times 320 \text{ nH}} \right)^2} - 1 \right) - 180 \text{ }\mu\text{F} = 48.5 \text{ mF}$$

where K = 4.6.

Using eight 560 µF Al-Poly capacitors with a typical ESR of 5 mΩ, each yields C<sub>X</sub> = 4.48 mF with an R<sub>X</sub> = 0.63 mΩ.

One last check should be made to ensure that the ESL of the bulk capacitors (L<sub>X</sub>) is low enough to limit the high frequency ringing during a load change. This is tested using

$$L_x \leq C_z \times R_O^2 \times Q^2 \quad (14)$$

$$L_x \leq 180 \text{ }\mu\text{F} \times (1 \text{ m}\Omega)^2 \times 2 = 360 \text{ pH}$$

where Q is limited to the square root of 2 to ensure a critically damped system.

In this example, L<sub>X</sub> is approximately 350 pH for the eight aluminum polymer capacitors, which satisfies this limitation. If the L<sub>X</sub> of the chosen bulk capacitor bank is too large, the number of ceramic capacitors may need to be increased if there is excessive ringing.

For this multimode control technique, all ceramic designs can be used as long as the conditions of Equation 11, Equation 12, and Equation 13 are satisfied.

## POWER MOSFETS

For this example, the N-channel power MOSFETs have been selected for one high-side switch and two low-side switches per phase. The main selection parameters for the power MOSFETs are V<sub>GS(TH)</sub>, Q<sub>G</sub>, C<sub>ISS</sub>, C<sub>RSS</sub>, and R<sub>DS(ON)</sub>. The minimum gate drive voltage (the supply voltage to the ADP3120A) dictates whether standard threshold or logic-level threshold MOSFETs must be used. With V<sub>GATE</sub> ~10 V, logic-level threshold MOSFETs (V<sub>GS(TH)</sub> < 2.5 V) are recommended.

The maximum output current ( $I_O$ ) determines the  $R_{DS(ON)}$  requirement for the low-side (synchronous) MOSFETs. With the ADP3190, currents are balanced between phases, thus the current in each low-side MOSFET is the output current divided by the total number of MOSFETs ( $n_{SF}$ ). With conduction losses being dominant, Equation 15 shows the total power being dissipated in each synchronous MOSFET in terms of the ripple current per phase ( $I_R$ ) and average total output current ( $I_O$ ):

$$P_{SF} = (1 - D) \times \left[ \left( \frac{I_O}{n_{SF}} \right)^2 + \frac{1}{12} \times \left( \frac{n I_R}{n_{SF}} \right)^2 \right] \times R_{DS(SF)} \quad (15)$$

Knowing the maximum output current being designed for and the maximum allowed power dissipation, it is possible to find the required  $R_{DS(ON)}$  for the MOSFET. For D-PAK MOSFETs up to an ambient temperature of 50°C, a safe limit for  $P_{SF}$  is 1 W to 1.5 W at 120°C junction temperature. Thus, for this example (119 A maximum),  $R_{DS(SF)}$  (per MOSFET) < 7.5 mΩ. This  $R_{DS(SF)}$  is also at a junction temperature of about 120°C, so be certain to account for this temperature when making this selection. This example uses two lower-side MOSFETs at 4.8 mΩ each at 120°C.

Another important factor for the synchronous MOSFET is the input capacitance and feedback capacitance. The ratio of the feedback to input needs to be small (less than 10% is recommended) to prevent accidental turn-on of the synchronous MOSFETs when the switch node goes high.

Also, the time to switch the synchronous MOSFETs off should not exceed the nonoverlap dead time of the MOSFET driver (40 ns typical for the ADP3120A). The output impedance of the driver is approximately 2 Ω, and the typical MOSFET input gate resistances are about 1 Ω to 2 Ω, so a total gate capacitance of less than 6000 pF should be adhered to. Because there are two MOSFETs in parallel, the input capacitance for each synchronous MOSFET should be limited to 3000 pF.

The high-side (main) MOSFET has to be able to handle two main power dissipation components: conduction and switching losses. The switching loss is related to the amount of time it takes for the main MOSFET to turn on and off, and to the current and voltage that are being switched.

Basing the switching speed on the rise and fall time of the gate driver impedance and MOSFET input capacitance, Equation 16 provides an approximate value for the switching loss per main MOSFET.

$$P_{S(MF)} = 2 \times f_{SW} \times \frac{V_{CC} \times I_O}{n_{MF}} \times R_G \times \frac{n_{MF}}{n} \times C_{ISS} \quad (16)$$

where:

$n_{MF}$  is the total number of main MOSFETs.

$R_G$  is the total gate resistance (2 Ω for the ADP3120A and about 1 Ω for typical high speed switching MOSFETs, making  $R_G = 3 \Omega$ )

$C_{ISS}$  is the input capacitance of the main MOSFET.

Adding more main MOSFETs ( $n_{MF}$ ) does not really help the switching loss per MOSFET because the additional gate capacitance slows switching. The best way to reduce switching loss is to use lower gate capacitance devices.

The conduction loss of the main MOSFET is given by the following, where  $R_{DS(MF)}$  is the on resistance of the MOSFET:

$$P_{C(MF)} = D \times \left[ \left( \frac{I_O}{n_{MF}} \right)^2 + \frac{1}{12} \times \left( \frac{n \times I_R}{n_{MF}} \right)^2 \right] \times R_{DS(MF)} \quad (17)$$

Typically, for main MOSFETs, the highest speed (low  $C_{ISS}$ ) device is preferred, but these usually have higher on resistance. Select a device that meets the total power dissipation (about 1.5 W for a single D-PAK) when combining the switching and conduction losses.

For this example, an NTD40N03L was selected as the main MOSFET (eight total;  $n_{MF} = 8$ ), with a  $C_{ISS} = 584$  pF (maximum) and  $R_{DS(MF)} = 19$  mΩ (maximum at  $T_J = 120^\circ\text{C}$ ). An NTD110N02L was selected as the synchronous MOSFET (eight total;  $n_{SF} = 8$ ), with  $C_{ISS} = 2710$  pF (maximum) and  $R_{DS(SF)} = 4.8$  mΩ (maximum at  $T_J = 120^\circ\text{C}$ ). The synchronous MOSFET  $C_{ISS}$  is less than 3000 pF, satisfying that requirement. Solving for the power dissipation per MOSFET at  $I_O = 119$  A and  $I_R = 11$  A yields 958 mW for each synchronous MOSFET and 872 mW for each main MOSFET. These numbers comply with the guideline to limit the power dissipation to 1 W per MOSFET.

One last factor to consider is the power dissipation in the driver for each phase. This is best described in terms of the  $Q_G$  for the MOSFETs and is given by the following equation:

$$P_{DRV} = \left[ \frac{f_{SW}}{2 \times n} \times (n_{MF} \times Q_{GMF} + n_{SF} \times Q_{GSF}) + I_{CC} \right] \times V_{CC} \quad (18)$$

where  $Q_{GMF}$  is the total gate charge for each main MOSFET and  $Q_{GSF}$  is the total gate charge for each synchronous MOSFET.

Also shown is the standby dissipation factor ( $I_{CC} \times V_{CC}$ ) for the driver. For the ADP3120A, the maximum dissipation should be less than 400 mW. In this example, with  $I_{CC} = 7$  mA,  $Q_{GMF} = 5.8$  nC, and  $Q_{GSF} = 48$  nC, 297 mW is found in each driver, which is below the 400 mW dissipation limit. See the ADP3120A data sheet for more details.

## RAMP RESISTOR SELECTION

The ramp resistor ( $R_R$ ) is used for setting the size of the internal PWM ramp. The value of this resistor is chosen to provide the best combination of thermal balance, stability, and transient response. The following expression is used for determining the optimum value:

$$R_R = \frac{A_R \times L}{3 \times A_D \times R_{DS} \times C_R} \quad (19)$$

$$R_R = \frac{0.2 \times 320 \text{ nH}}{3 \times 5 \times 2.4 \text{ m}\Omega \times 5 \text{ pF}} = 356 \text{ k}\Omega$$

where  $A_R$  is the internal ramp amplifier gain,  $A_D$  is the current balancing amplifier gain,  $R_{DS}$  is the total low-side MOSFET on resistance, and  $C_R$  is the internal ramp capacitor value. The closest standard 1% resistor value is 357 k $\Omega$ .

The internal ramp voltage magnitude can be calculated by using

$$V_R = \frac{A_R \times (1 - D) \times V_{VID}}{R_R \times C_R \times f_{SW}} \quad (20)$$

$$V_R = \frac{0.2 \times (1 - 0.108) \times 1.3 \text{ V}}{357 \text{ k}\Omega \times 5 \text{ pF} \times 330 \text{ kHz}} = 390 \text{ mV}$$

The size of the internal ramp can be made larger or smaller. If it is made larger, stability and transient response improve, but thermal balance degrades. Likewise, if the ramp is made smaller, thermal balance improves at the sacrifice of transient response and stability. The factor of 3 in the denominator of Equation 19 sets a ramp size that gives an optimal balance for good stability, transient response, and thermal balance.

## COMP PIN RAMP

A ramp signal on the COMP pin is due to the droop voltage and output voltage ramps. This ramp amplitude adds to the internal ramp to produce the following overall ramp signal at the PWM input:

$$V_{RT} = \frac{V_R}{\left(1 - \frac{2 \times (1 - n \times D)}{n \times f_{SW} \times C_X \times R_O}\right)} \quad (21)$$

In this example, the overall ramp signal is 0.49 V.

## CURRENT-LIMIT SETPOINT

To select the current-limit set point, first find the resistor value for  $R_{LIM}$ . The current-limit threshold for the ADP3190 is set with a 3 V source ( $V_{LIM}$ ) across  $R_{LIM}$  with a gain of 10.4 mV/ $\mu$ A ( $A_{LIM}$ ).  $R_{LIM}$  can be found using

$$R_{LIM} = \frac{A_{LIM} \times V_{LIM}}{I_{LIM} \times R_O} \quad (22)$$

For values of  $R_{LIM}$  greater than 500 k $\Omega$ , the current limit can be lower than expected, so some adjustment of  $R_{LIM}$  may be needed. Here,  $I_{LIM}$  is the average current limit for the output of the supply. In this example, choosing a peak current limit of 200 A for  $I_{LIM}$  results in  $R_{LIM} = 156 \text{ k}\Omega$ , for which 150 k $\Omega$  is chosen as the nearest 1% value.

The limit of the per-phase current limit described earlier is determined by

$$I_{PHLIM} \cong \frac{V_{COMP(MAX)} - V_R - V_{BIAS}}{A_D \times R_{DS(MAX)}} + \frac{I_R}{2} \quad (23)$$

For the ADP3190, the maximum COMP voltage ( $V_{COMP(MAX)}$ ) is 3.3 V, the COMP pin bias voltage ( $V_{BIAS}$ ) is 1.2 V, and the current-balancing amplifier gain ( $A_D$ ) is 5. Using  $V_R$  of 0.49 V and  $R_{DS(MAX)}$  of 3 m $\Omega$  (low-side on resistance at 150°C), calculate a per-phase peak current limit of 100 A. Although this number may seem high, this current level can only be reached with an absolute short at the output, and the current-limit latch-off function shuts down the regulator before overheating can occur.

This limit can be adjusted by changing the ramp voltage ( $V_R$ ), but make sure not to set the per-phase limit lower than the average per-phase current ( $I_{LIM}/n$ ).

The per-phase initial duty cycle limit is determined by

$$D_{MAX} = D \times \frac{V_{COMP(MAX)} - V_{BIAS}}{V_{RT}} \quad (24)$$

In this example, the maximum duty cycle is 0.46.

## FEEDBACK LOOP COMPENSATION DESIGN

Optimized compensation of the ADP3190 allows the best possible response of the regulator's output to a load change. The basis for determining the optimum compensation is to make the regulator and output decoupling appear as an output impedance that is entirely resistive over the widest possible frequency range, including dc, and equal to the droop resistance ( $R_O$ ).

With the resistive output impedance, the output voltage droops in proportion to the load current at any load current slew rate. This ensures optimal positioning and allows minimization of the output decoupling.

With the multimode feedback structure of the ADP3190, the feedback compensation must be set to make the converter's output impedance, working in parallel with the output decoupling, to meet this goal. Several poles and zeros created by the output inductor and decoupling capacitors (output filter) need to be compensated for.

A type-three compensator on the voltage feedback is adequate for proper compensation of the output filter. Equation 25 to Equation 29 yield an optimal starting point for the design; some adjustments may be necessary to account for PCB and component parasitic effects (see the Layout and Component Placement section).

The first step is to compute the time constants for all of the poles and zeros in the system.

$$R_E = n \times R_O + A_D \times R_{DS} + \frac{R_L \times V_{RT}}{V_{VID}} + \frac{2 \times L \times (1 - n \times D) \times V_{RT}}{n \times C_X \times R_O \times V_{VID}}$$

$$R_E = 4 \times 1 \text{ m}\Omega + 5 \times 2.4 \text{ m}\Omega + \frac{1.4 \text{ m}\Omega \times 0.49 \text{ V}}{1.3 \text{ V}} + \frac{2 \times 320 \text{ nH} \times (1 - 0.432) \times 0.49 \text{ V}}{4 \times 4.45 \text{ mF} \times 1 \text{ m}\Omega \times 1.3 \text{ V}} = 24.2 \text{ m}\Omega \quad (25)$$

$$T_A = C_X \times (R_O - R') + \frac{L_X}{R_O} \times \frac{R_O - R'}{R_X} = 4.45 \text{ mF} \times (1 \text{ m}\Omega - 0.5 \text{ m}\Omega) + \frac{350 \text{ pH}}{1 \text{ m}\Omega} \times \frac{1 \text{ m}\Omega - 0.65 \text{ m}\Omega}{10.63 \text{ m}\Omega} = 2.50 \text{ }\mu\text{s} \quad (26)$$

$$T_B = (R_X + R' - R_O) \times C_X = (0.63 \text{ m}\Omega + 0.5 \text{ m}\Omega - 1 \text{ m}\Omega) \times 4.45 \text{ mF} = 580 \text{ ns} \quad (27)$$

$$T_C = \frac{V_{RT} \times \left( L - \frac{A_D \times R_{DS}}{2 \times f_{SW}} \right)}{V_{VID} \times R_E} = \frac{0.49 \text{ V} \times \left( 320 \text{ nH} - \frac{5 \times 2.4 \text{ m}\Omega}{2 \times 330 \text{ kHz}} \right)}{1.3 \text{ V} \times 24.2 \text{ m}\Omega} = 4.7 \text{ }\mu\text{s} \quad (28)$$

$$T_D = \frac{C_X \times C_Z \times R_O^2}{C_X \times (R_O - R') + C_Z \times R_O} = \frac{4.45 \text{ mF} \times 180 \text{ }\mu\text{F} \times (1 \text{ m}\Omega)^2}{4.45 \text{ mF} \times (1 \text{ m}\Omega - 0.5 \text{ m}\Omega) + 180 \text{ }\mu\text{F} \times 1 \text{ m}\Omega} = 333 \text{ ns} \quad (29)$$

where  $R'$  is the PCB resistance from the bulk capacitors to the ceramics and  $R_{DS}$  is the total low-side MOSFET on resistance per phase.

In this example,  $A_D$  is 5,  $V_{RT}$  equals 0.49 V,  $R'$  is approximately 0.5 m $\Omega$  (assuming a 4-layer, 1 ounce motherboard), and  $L_X$  is 350 pH for the eight aluminum polymer capacitors.

The compensation values can then be solved using the following:

$$C_A = \frac{n \times R_O \times T_A}{R_E \times R_B} \quad (30)$$

$$C_A = \frac{4 \times 1 \text{ m}\Omega \times 2.50 \text{ }\mu\text{s}}{24.2 \text{ m}\Omega \times 1.21 \text{ k}\Omega} = 342 \text{ pF}$$

$$R_A = \frac{T_C}{C_A} = \frac{4.7 \text{ }\mu\text{s}}{342 \text{ pF}} = 13.7 \text{ k}\Omega \quad (31)$$

$$C_B = \frac{T_B}{R_B} = \frac{580 \text{ ns}}{1.21 \text{ k}\Omega} = 479 \text{ nF} \quad (32)$$

$$C_{FB} = \frac{T_D}{R_A} = \frac{333 \text{ ns}}{13.7 \text{ k}\Omega} = 24.3 \text{ pF} \quad (33)$$

These are the starting values, prior to tuning the design, to account for layout and other parasitic effects (see the Layout and Component Placement section).

The final values selected after tuning are

$$\begin{aligned} C_A &= 470 \text{ pF} \\ R_A &= 12.1 \text{ k}\Omega \\ C_B &= 470 \text{ pF} \\ C_{FB} &= 22 \text{ pF} \end{aligned}$$

Figure 11 and Figure 12 show the typical transient response using these compensation values.

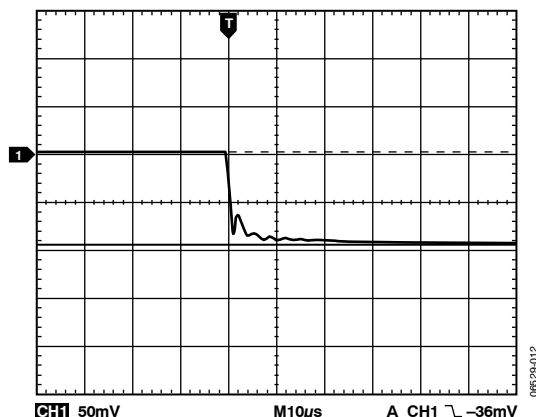


Figure 11. Typical Transient Response for Design Example Load Step

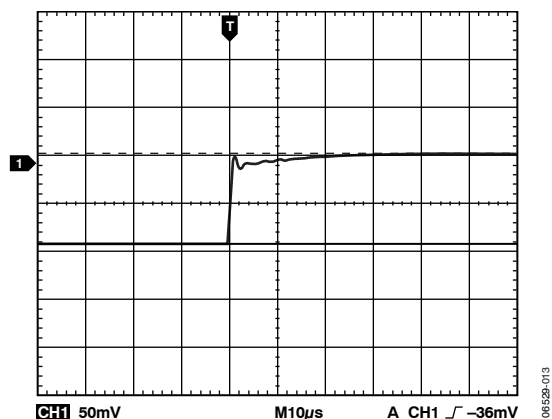


Figure 12. Typical Transient Response for Design Example Load Release

## C<sub>IN</sub> SELECTION AND INPUT CURRENT di/dt REDUCTION

In continuous inductor current mode, the source current of the high-side MOSFET is approximately a square wave with a duty ratio equal to  $n \times V_{OUT}/V_{IN}$  and an amplitude of one- $n$ th the maximum output current. To prevent large voltage transients, a low ESR input capacitor, sized for the maximum rms current, must be used. The maximum rms capacitor current is given by

$$I_{CRMS} = D \times I_O \times \sqrt{\frac{1}{N \times D} - 1} \quad (34)$$

$$I_{CRMS} = 0.108 \times 119 \text{ A} \times \sqrt{\frac{1}{4 \times 0.108} - 1} = 14.7 \text{ A}$$

The capacitor manufacturer's ripple current ratings are often based on only 2000 hours of life. This makes it advisable to further derate the capacitor or to choose a capacitor rated at a higher temperature than required. Several capacitors can be placed in parallel to meet size or height requirements in the design. In this example, the input capacitor bank is formed by

two 2700 µF, 16 V aluminum electrolytic capacitors and eight 4.7 µF ceramic capacitors.

To reduce the input current  $di/dt$  to a level below the recommended maximum of 0.1 A/µs, an additional small inductor ( $L > 370 \text{ nH}$  at 18 A) should be inserted between the converter and the supply bus. This inductor also acts as a filter between the converter and the primary power source.

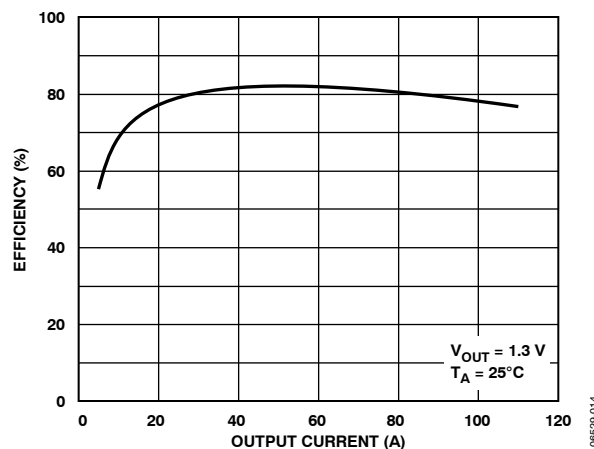


Figure 13. Efficiency of the Circuit of Figure 10 vs. Output Current

## TUNING THE ADP3190

1. Build a circuit based on the compensation values computed from the design spreadsheet.
2. Hook up the dc load to circuit, turn it on, and verify its operation. Also, check for jitter at no load and full load.

### DC Load Line Setting

3. Measure the output voltage at no load ( $V_{NL}$ ). Verify that it is within tolerance.
4. Measure the output voltage at full load cold ( $V_{FLCOLD}$ ). Let the board sit for ~10 minutes at full load, and then measure the output ( $V_{FLHOT}$ ). If there is a change of more than a few millivolts, adjust  $R_{CS1}$  and  $R_{CS2}$ , using Equation 35 and Equation 36.

$$R_{CS2(NEW)} = R_{CS2(OLD)} \times \frac{V_{NL} - V_{FLCOLD}}{V_{NL} - V_{FLHOT}} \quad (35)$$

5. Repeat Step 4 until the cold and hot voltage measurements remain the same.
6. Measure the output voltage from no load to full load, using 5 A steps. Compute the load line slope for each change, and then average to get the overall load line slope ( $R_{OMEAS}$ ).
7. If  $R_{OMEAS}$  is off from  $R_O$  by more than 0.05 mΩ, use Equation 37 to adjust the  $R_{PH}$  values.

$$R_{PH(NEW)} = R_{PH(OLD)} \times \frac{R_{OMEAS}}{R_O} \quad (37)$$

8. Repeat Step 6 and Step 7 to check the load line, and repeat adjustments if necessary.

- Once dc load line adjustment is complete, do not change  $R_{PH}$ ,  $R_{CS1}$ ,  $R_{CS2}$ , or  $R_{TH}$  for the remainder of the procedure.

- Measure the output ripple at no load and full load with a scope, and make sure it is within specifications.

$$R_{CS1(NEW)} = \frac{1}{\frac{R_{CS1(OLD)} + R_{TH(25^{\circ}C)}}{R_{CS1(OLD)} \times R_{TH(25^{\circ}C)} + (R_{CS1(OLD)} - R_{CS2(NEW)}) \times (R_{CS1(OLD)} - R_{TH(25^{\circ}C)})} - \frac{1}{R_{TH(25^{\circ}C)}}} \quad (36)$$

## AC Load Line Setting

- Remove the dc load from the circuit and hook up the dynamic load.
- Hook up the scope to the output voltage and set it to dc coupling, with the time scale at 100  $\mu$ s/div.
- Set the dynamic load for a transient step of about 40 A at 1 kHz with a 50% duty cycle.
- Measure the output waveform (if not visible, use dc offset on scope to view). Try to use a vertical scale of 100 mV/div or finer. This waveform should look similar to Figure 14.

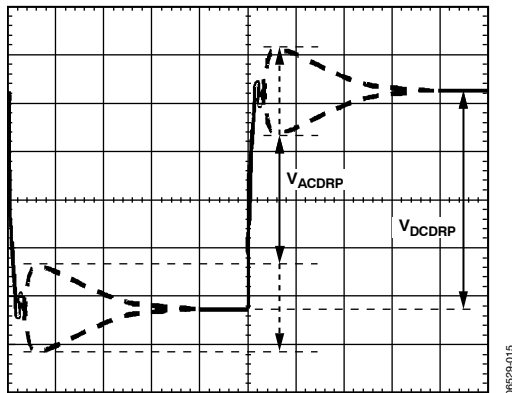


Figure 14. AC Load Line Waveform

- Use the horizontal cursors to measure  $V_{ACDRP}$  and  $V_{DCDRP}$ , as shown. Do not measure the undershoot or overshoot that happens immediately after this step.

If  $V_{ACDRP}$  and  $V_{DCDRP}$  are different by more than a few millivolts, use Equation 38 to adjust  $C_{CS}$ . It may be necessary to parallel different values to get the correct one, because there are limited standard capacitor values available. It is a good idea to have locations for two capacitors in the layout for this.

$$C_{CS(NEW)} = C_{CS(OLD)} \times \frac{V_{ACDRP}}{V_{DCDRP}} \quad (38)$$

- Repeat Step 11 to Step 13, and repeat the adjustments, if necessary. Once complete, do not change  $C_{CS}$  for the remainder of the procedure.

Set the dynamic load step to maximum step size. Do not use a step size larger than needed, and verify that the output

waveform is square, which means that  $V_{ACDRP}$  and  $V_{DCDRP}$  are equal.

## Initial Transient Setting

- With the dynamic load still set at the maximum step size, expand the scope time scale to see 2  $\mu$ s/div to 5  $\mu$ s/div. The waveform may have two overshoots and one minor undershoot (see Figure 15). Here,  $V_{DROOP}$  is the final desired value.

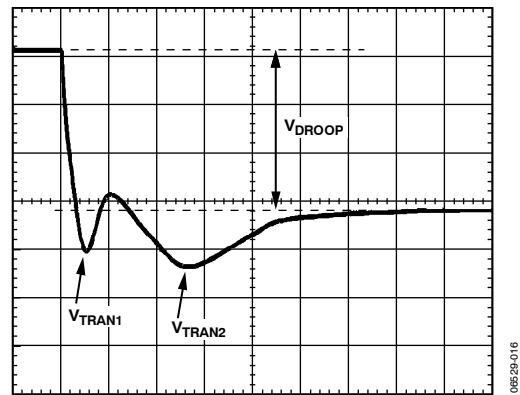


Figure 15. Transient Setting Waveform

- If both overshoots are larger than desired, try making the following adjustments:
  - Make the ramp resistor larger by 25% ( $R_{RAMP}$ ).
  - For  $V_{TRAN1}$ , increase  $C_B$  or increase the switching frequency.
  - For  $V_{TRAN2}$ , increase  $R_A$  and decrease  $C_A$  by 25%.

If these adjustments do not change the response, the output decoupling is the limiting factor. Check the output response every time a change is made, or nodes are switched, to make sure the response remains stable.

- For load release (see Figure 16), if  $V_{TRANREL}$  is larger than  $V_{TRAN1}$  (see Figure 15), there is not enough output capacitance. Either more capacitance is needed or the inductor values need to be smaller. If inductors are changed, start the design again using the spreadsheet and this tuning procedure.

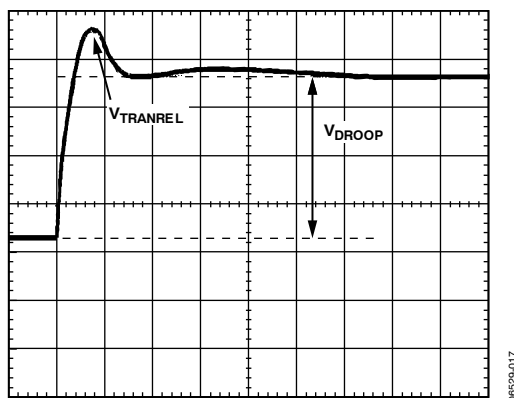


Figure 16. Transient Setting Waveform

Because the ADP3190 turns off all of the phases (switches inductors to ground), there is no ripple voltage present during

load release. Thus, headroom does not need to be added for ripple, allowing load release,  $V_{TRANREL}$ , to be larger than  $V_{TRAN1}$  by the amount of ripple and still meet specifications.

If  $V_{TRAN1}$  and  $V_{TRANREL}$  are less than the desired final droop, this implies that capacitors can be removed. When removing capacitors, also check the output ripple voltage to make sure it is still within specifications.

## REPLACING THE ADP3188 WITH THE ADP3190

Figure 17 shows the changes needed when replacing an existing ADP3188 design with the ADP3190. The shunt resistor needs to be rated for  $\frac{1}{4}$  W.

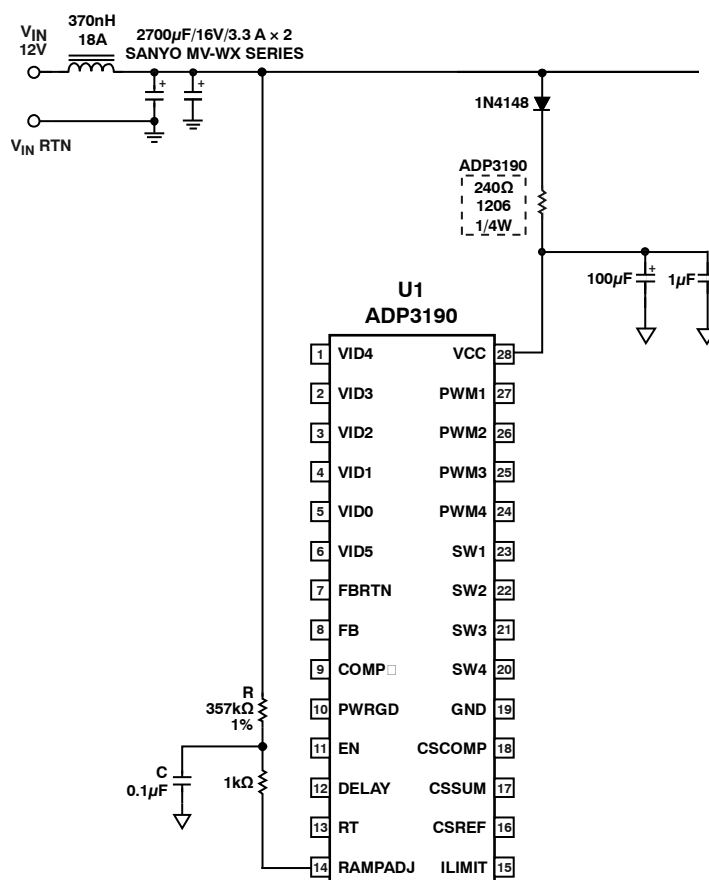


Figure 17. Replacing the ADP3188 with the ADP3190



## CHOOSING BETWEEN THE ADP3190 AND THE ADP3190A

For existing designs using the ADP3188, the ADP3190 is the recommended replacement. For new designs where 5 V system

voltage is available, it is recommended to use the ADP3190A, as configured in Figure 18. For correct power sequencing, ensure that the 12 V rail is present before the 5 V  $V_{IN}$  is applied to the ADP3190A.

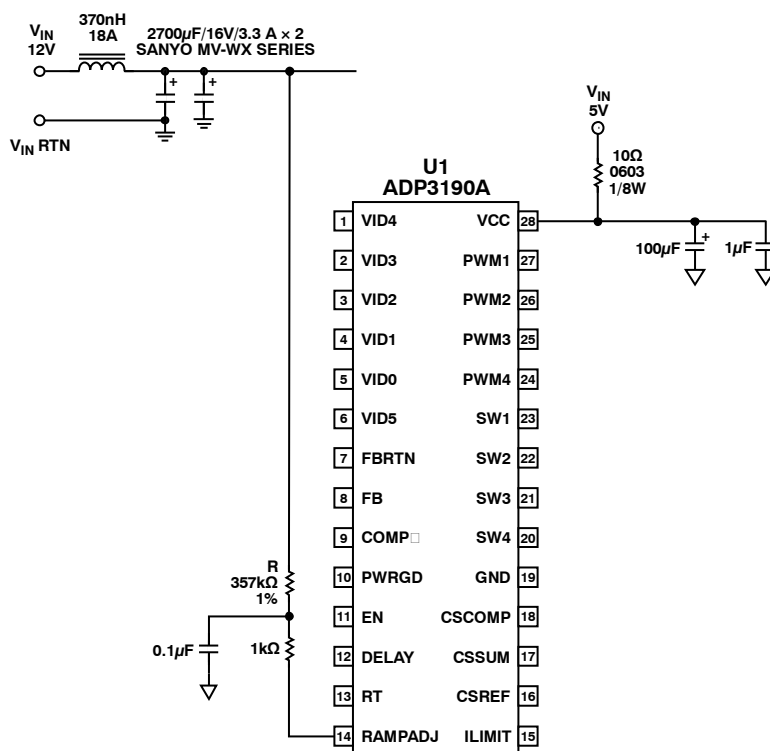


Figure 18. Replacing the ADP3188 with the ADP3190A

## LAYOUT AND COMPONENT PLACEMENT

The following guidelines are recommended for optimal performance of a switching regulator in a PC system.

### GENERAL RECOMMENDATIONS

- For good results, a PCB with at least four layers is recommended. This allows the needed versatility for control circuitry interconnections with optimal placement; power planes for ground, input, and output power; and wide interconnection traces in the remainder of the power delivery current paths.  
  
Note that each square unit of 1 ounce copper trace has a resistance of  $\sim 0.53 \text{ m}\Omega$  at room temperature.
- Whenever high currents must be routed between PCB layers, vias should be used liberally to create several parallel current paths. Then, the resistance and inductance introduced by these current paths is minimized, and the via current rating is not exceeded.
- If critical signal lines, including the output voltage sense lines of the ADP3190, must cross through power circuitry, it is best if a signal ground plane can be interposed between those signal lines and the traces of the power circuitry. This serves as a shield to minimize noise injection into the signals at the expense of making signal ground noisier.
- Use an analog ground plane around and under the ADP3190 as a reference for the components associated with the controller. This plane should be tied to the nearest output decoupling capacitor ground and not tied to any other power circuitry. This prevents power currents from flowing in the ground plane.
- Locate the components around the ADP3190 close to the controller with short traces. The most important traces to keep short, and away from other traces, are the FB pin and the CSSUM pin. Connect the output capacitors as close as possible to the load (or connector), for example, a micro-processor core that receives the power. If the load is distributed, the capacitors should also be distributed and generally be in proportion to where the load tends to be more dynamic.
- Avoid crossing any signal lines over the switching power path loop, as described in the Power Circuitry Recommendations section.

### POWER CIRCUITRY RECOMMENDATIONS

- The switching power path should be routed on the PCB to encompass the shortest possible length in order to minimize radiated switching noise energy (that is, EMI) and conduction losses in the board. Failure to take proper precautions often results in EMI problems for the entire PC system as well as noise-related operational problems in the power converter control circuitry. The switching power path is the loop formed by the current path through the input capacitors and the power MOSFETs, including all interconnecting PCB traces and planes. Using short and wide interconnection traces is especially critical in this path for two reasons: it minimizes the inductance in the switching loop, which can cause high energy ringing, and it accommodates the high current demand with minimal voltage loss.
- Whenever a power dissipating component, (for example, a power MOSFET), is soldered to a PCB, the liberal use of vias, both directly on the mounting pad and immediately surrounding it, is recommended. This improves current rating through the vias and also improves thermal performance from vias extended to the opposite side of the PCB, where a plane can more readily transfer the heat to the air. Make a mirror image of any pad being used to heat-sink the MOSFETs on the opposite side of the PCB to achieve the best thermal dissipation to the air around the board. To further improve thermal performance, use the largest possible pad area.
- The output power path should also be routed to encompass a short distance. The output power path is formed by the current path through the inductor, the output capacitors, and the load.
- For best EMI containment, a solid power ground plane should be used as one of the inner layers extending fully under all the power components.

### SIGNAL CIRCUITRY RECOMMENDATIONS

- The output voltage is sensed and regulated between the FB pin and the FBRTN pin, which connect to the signal ground at the load. To avoid differential-mode noise pickup in the sensed signal, the loop area should be small. Thus, the FB and FBRTN traces should be routed adjacent to each other on top of the power ground plane back to the controller.
- The feedback traces from the switch nodes should be connected as close as possible to the inductor. The CSREF signal should be connected to the output voltage at the nearest inductor to the controller.

## OUTLINE DIMENSIONS

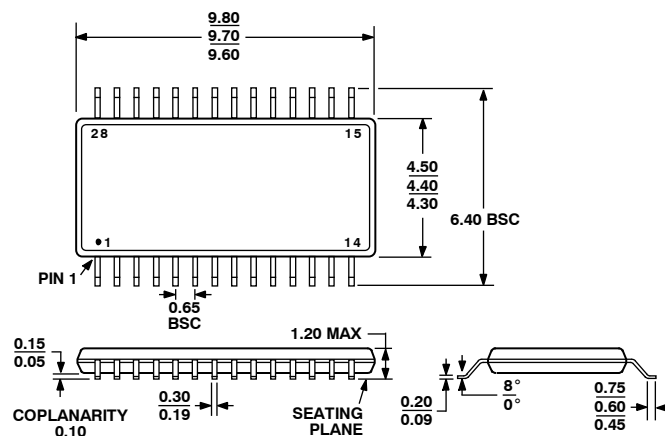


Figure 19. 28-Lead Thin Shrink Small Outline Package [TSSOP]  
(RU-28)

Dimensions shown in millimeters

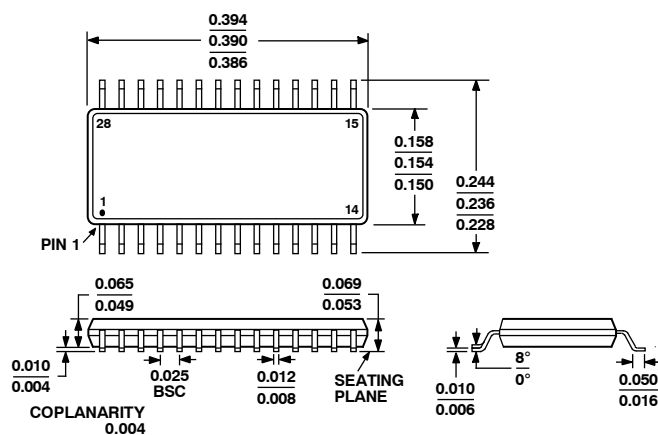


Figure 20. 28-Lead Shrink Small Outline Package [QSOP]  
(RQ-28)

Dimensions shown in inches

## ORDERING GUIDE

| Model                        | Temperature Range | System Supply | Package Description     | Package Option | Ordering Quantity |
|------------------------------|-------------------|---------------|-------------------------|----------------|-------------------|
| ADP3190JRUZ-RL <sup>1</sup>  | 0°C to 85°C       | 12 V          | 28-Lead TSSOP, 13" Reel | RU-28          | 2,500             |
| ADP3190JRQZ-RL <sup>1</sup>  | 0°C to 85°C       | 12 V          | 28-Lead QSOP, 13" Reel  | RQ-28          | 2,500             |
| ADP3190AJRUZ-RL <sup>1</sup> | 0°C to 85°C       | 5 V           | 28-Lead TSSOP, 13" Reel | RU-28          | 2,500             |
| ADP3190AJRQZ-RL <sup>1</sup> | 0°C to 85°C       | 5 V           | 28-Lead QSOP, 13" Reel  | RQ-28          | 2,500             |

<sup>1</sup> Z = Pb-free part.

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